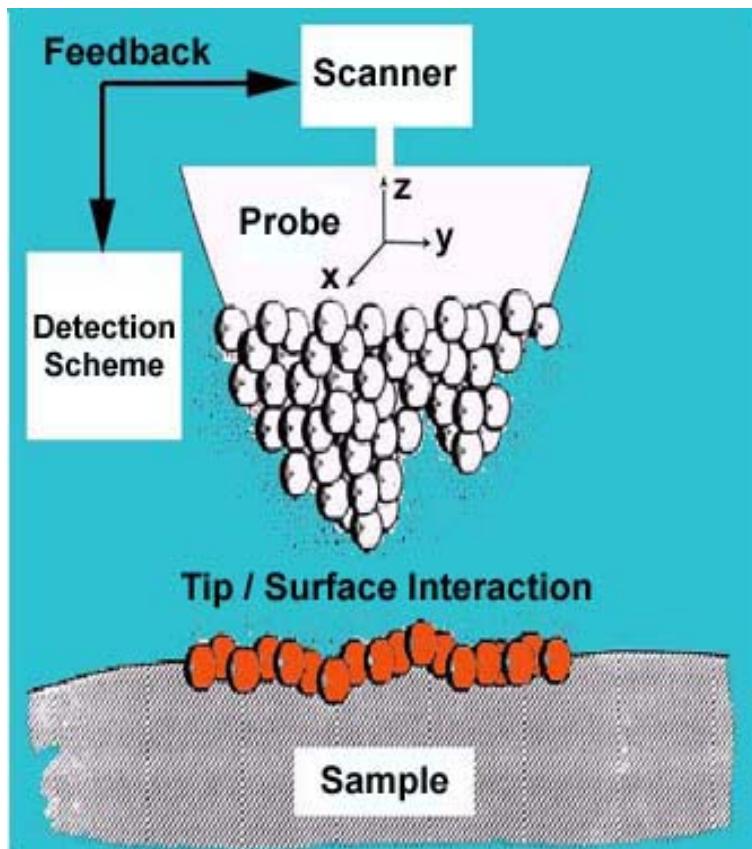


Scanning Probe Microscopy (SPM)



Scanning Tunneling Microscopy (STM)

--- G. Binnig, H. Rohrer et al, (1982)

Near-Field Scanning Optical Microscopy (NSOM)

--- D. W. Pohl (1982)

Atomic Force Microscopy (AFM)

--- G. Binnig, C. F. Quate, C. Gerber (1986)

Scanning Thermal Microscopy (SThM)

--- C. C. Williams, H. Wickramasinghe (1986)

Magnetic Force Microscopy (MFM)

--- Y. Martin, H. K. Wickramasinghe (1987)

Friction Force Microscopy (FFM or LFM)

--- C. M. Mate et al (1987)

Electrostatic Force Microscopy (EFM)

--- Y. Martin, D. W. Abraham et al (1988)

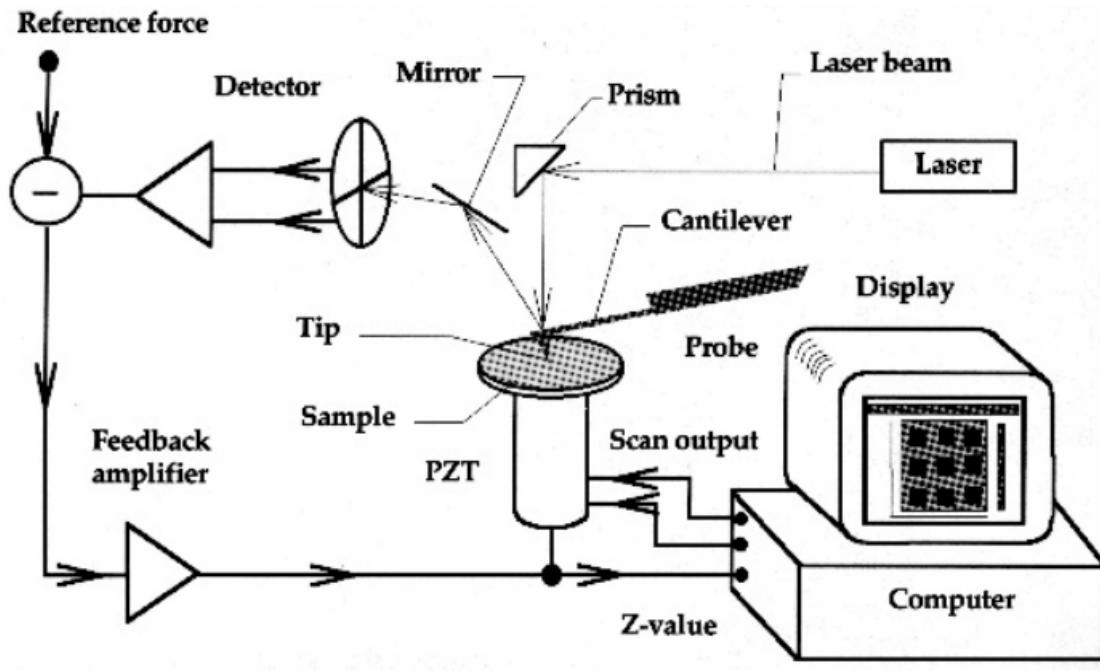
Scanning Capacitance Microscopy (SCM)

--- C. C. Williams, J. Slinkman et al (1989)

Force Modulation Microscopy (FMM)

--- P. Maivald et al (1991)

Atomic Force Microscopy (AFM)



$$F = k\Delta z$$

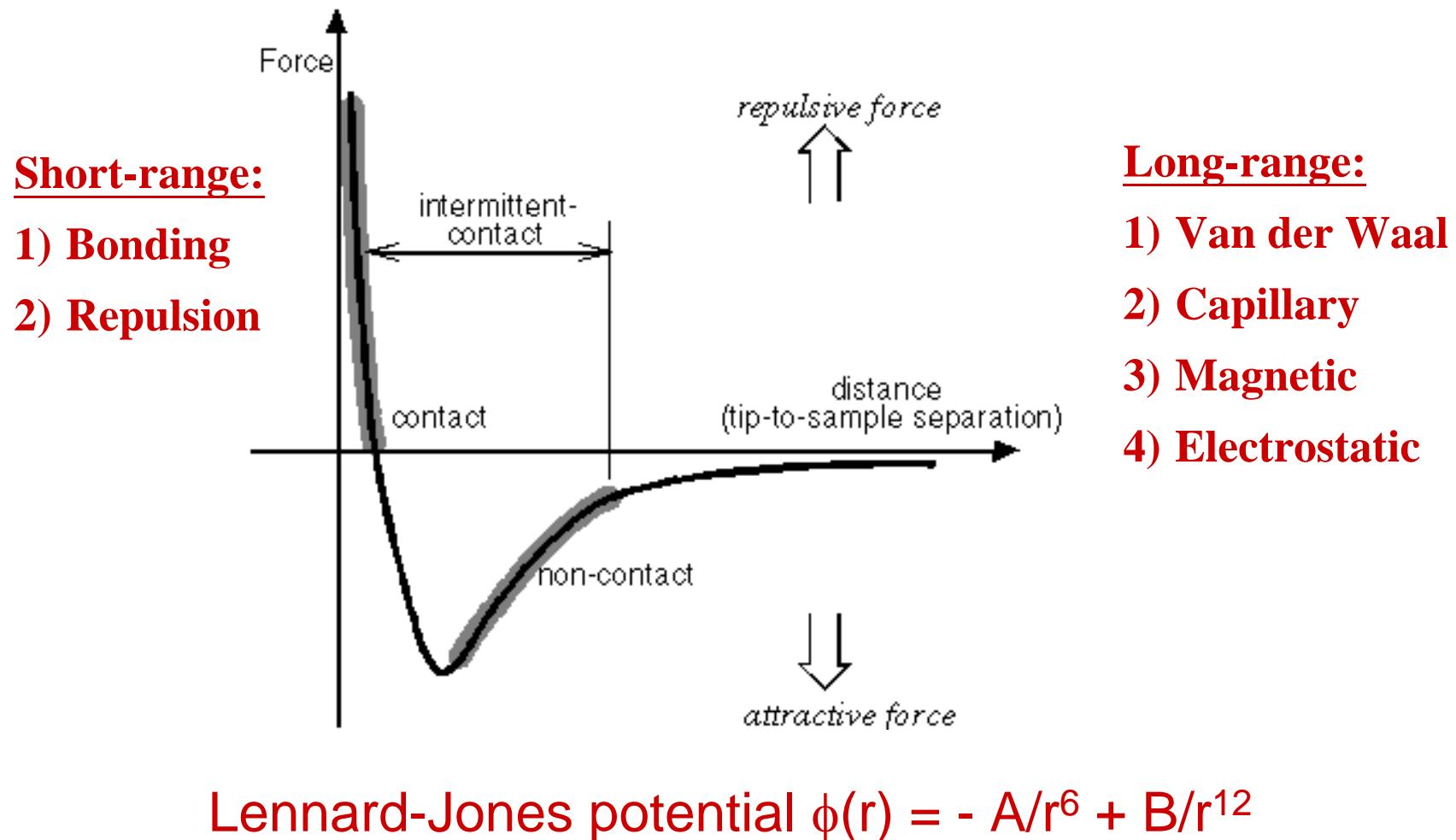
$$F = 10^{-9} - 10^{-6} \text{ N}$$

$$k = 0.1 - 1 \text{ N/m}$$

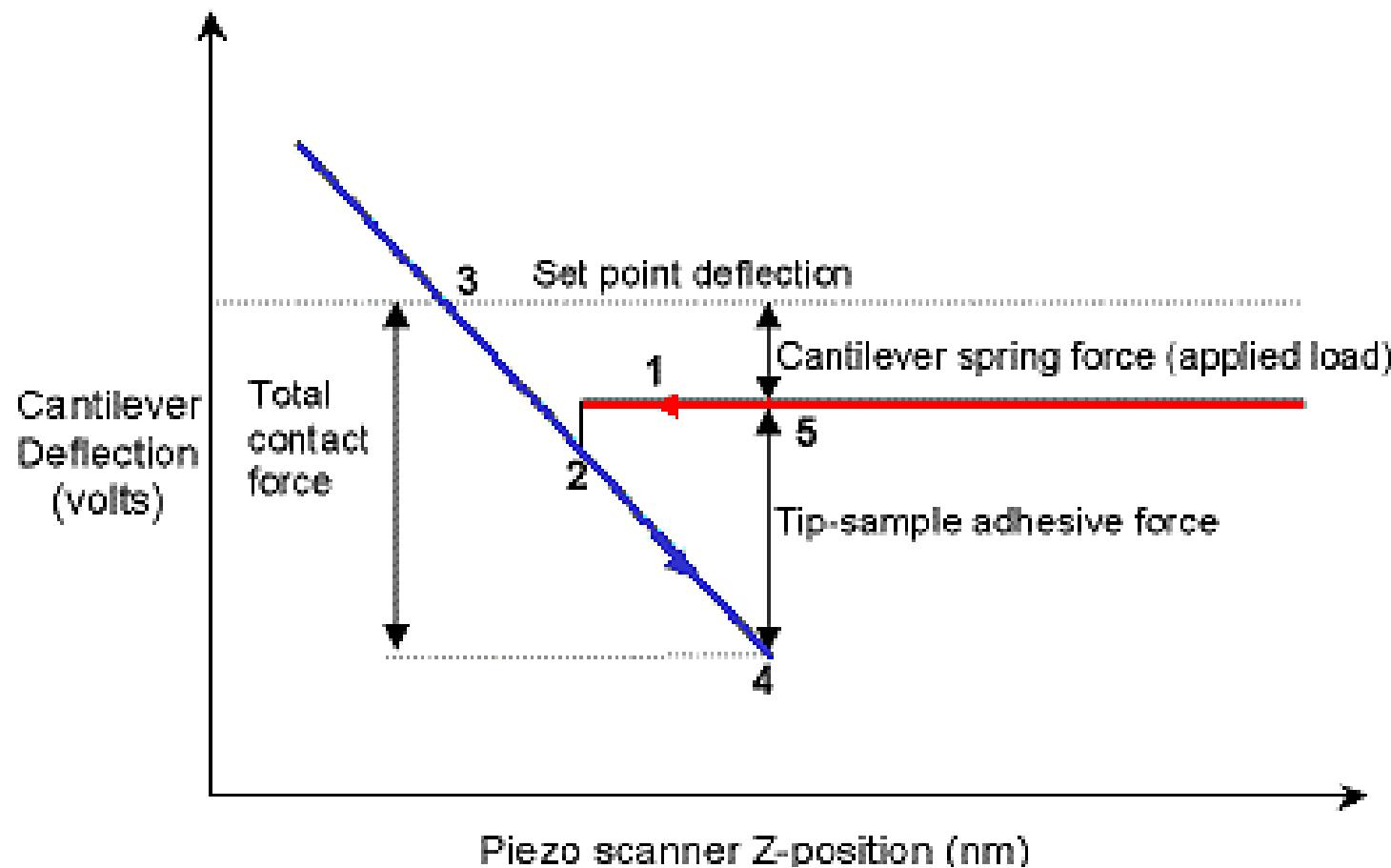
References:

- G. Binnig, C. F. Quate, and C. Gerber, Phys. Rev. Lett. 56, 930 (1986).
- C. Bustamante and D. Keller, Physics Today, 32, December (1995).
- R. Wiesendanger and H.J. Güntherodt, *Scanning Tunneling Microscopy II*, Springer-Verlag, (1992).

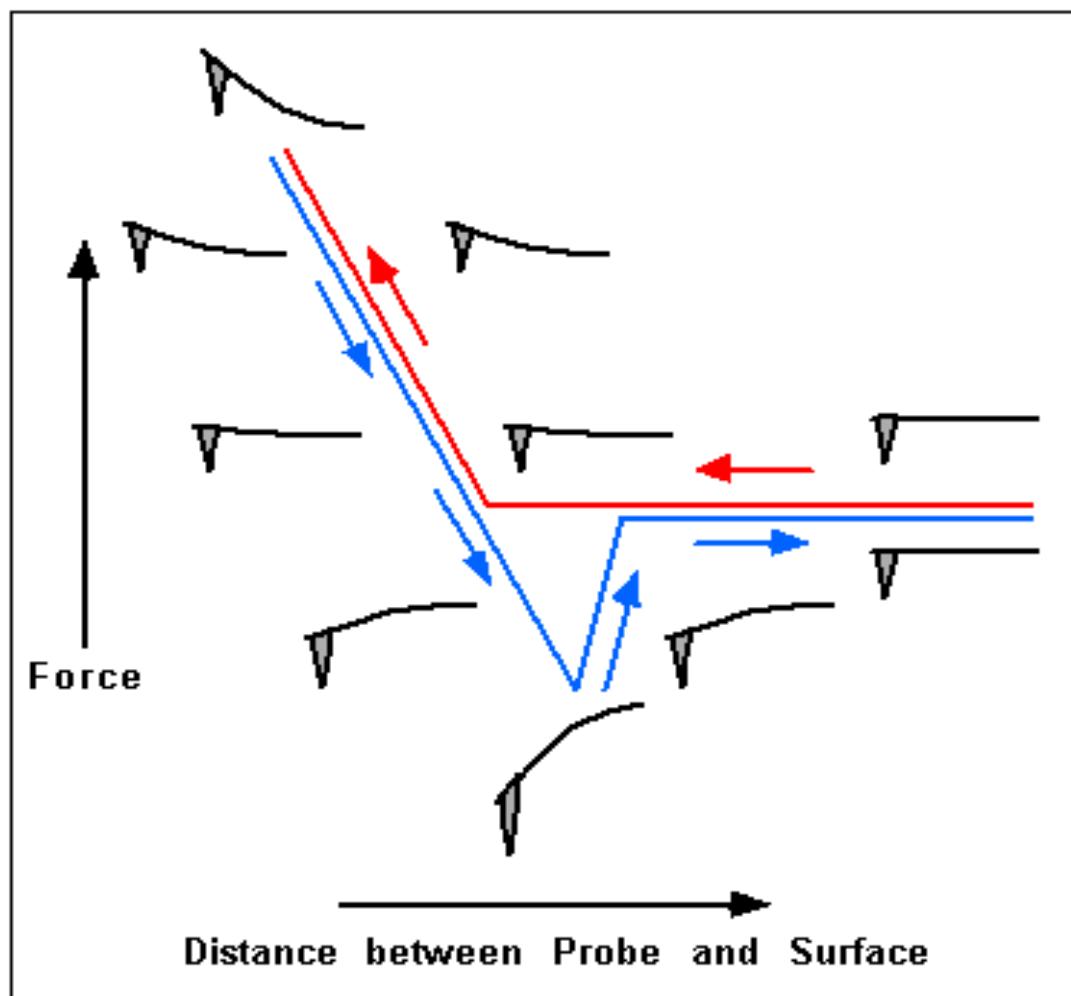
Interaction between the probe and sample



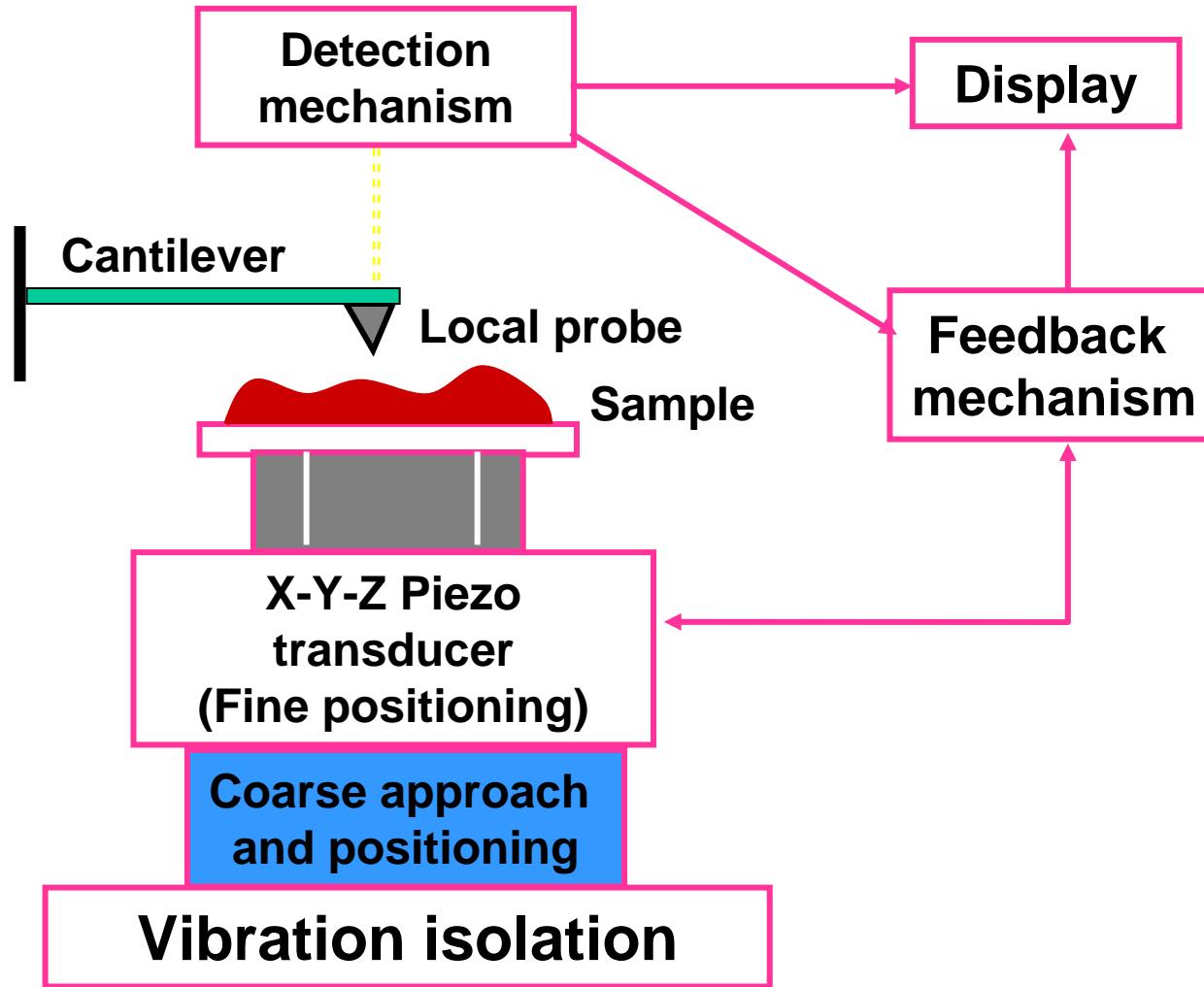
Deflection of Cantilever vs Piezo displacement



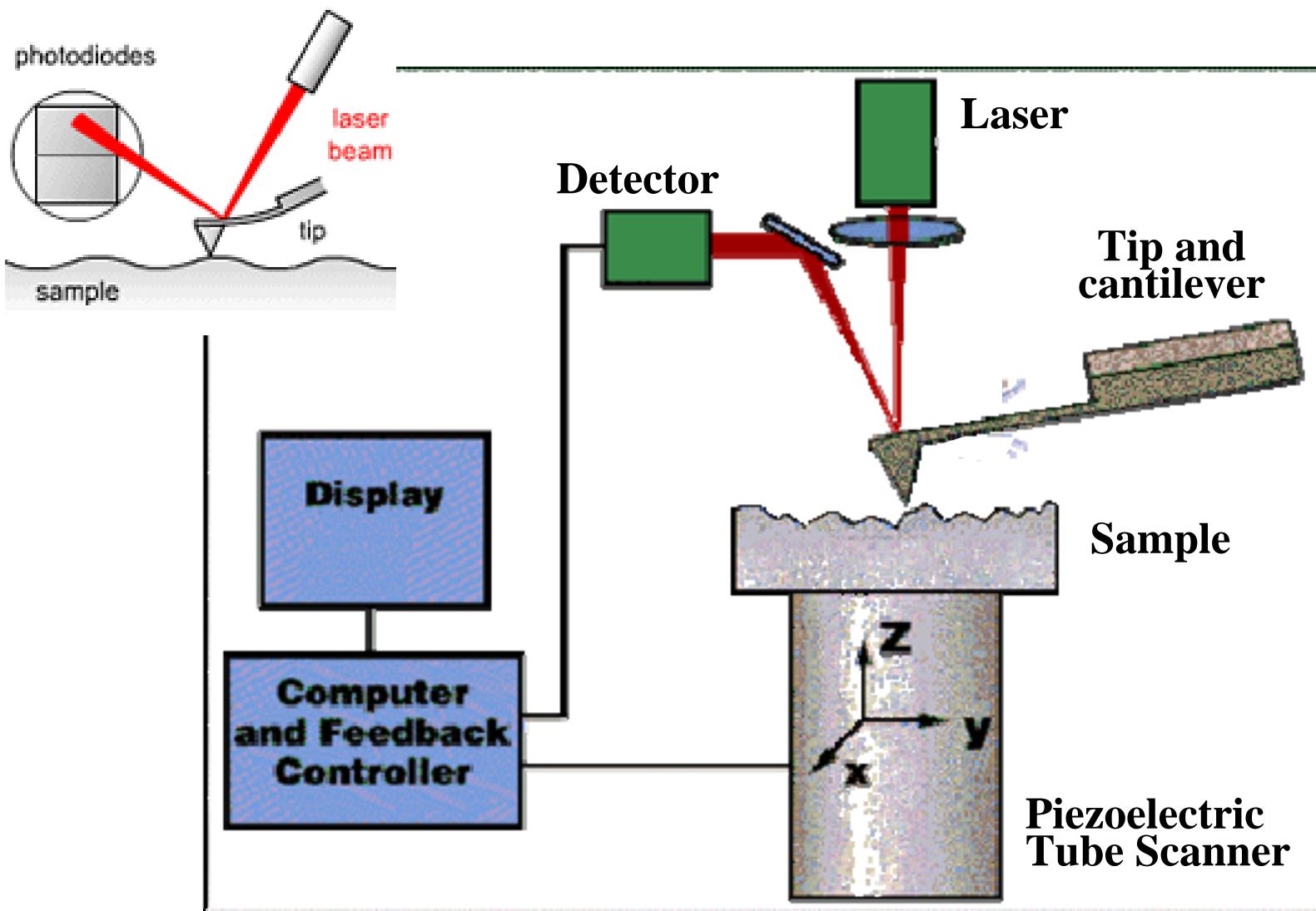
Reaction of the probe to the force



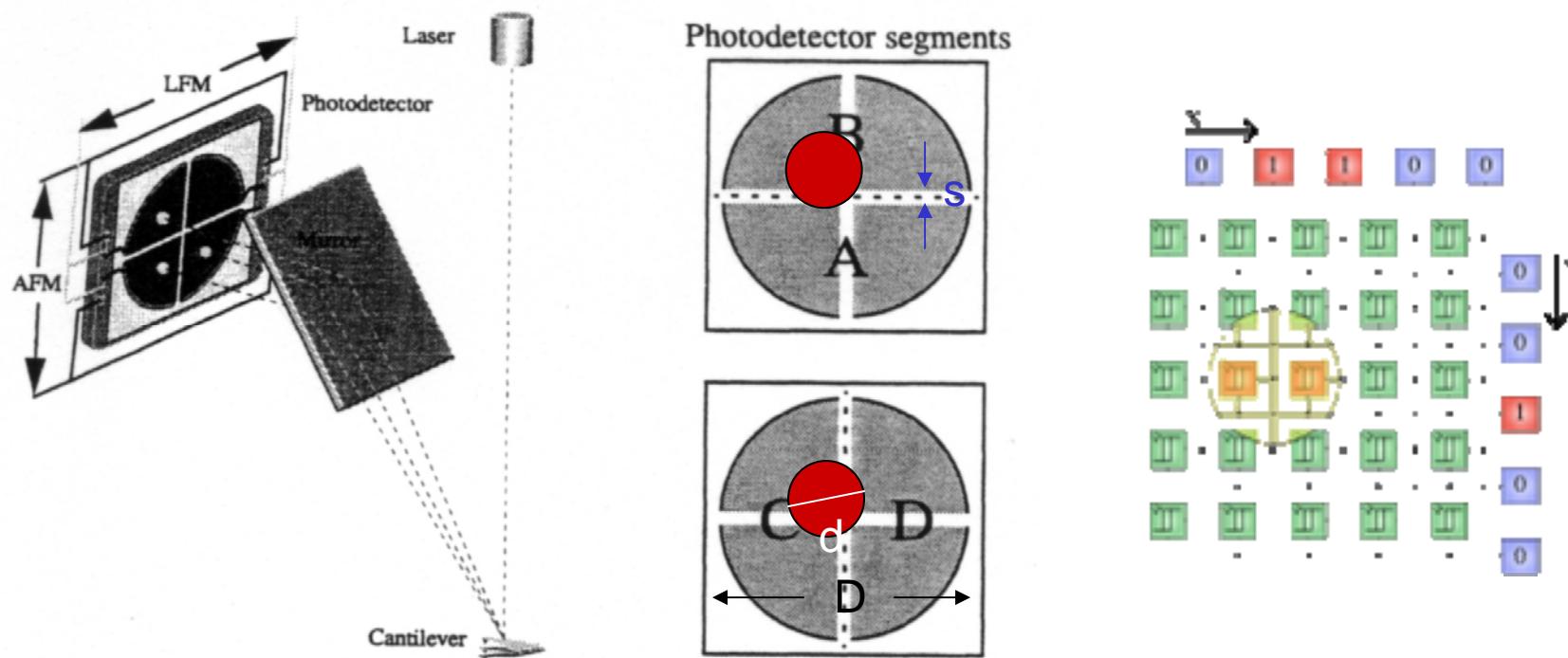
Structure of AFM



Core components of AFM

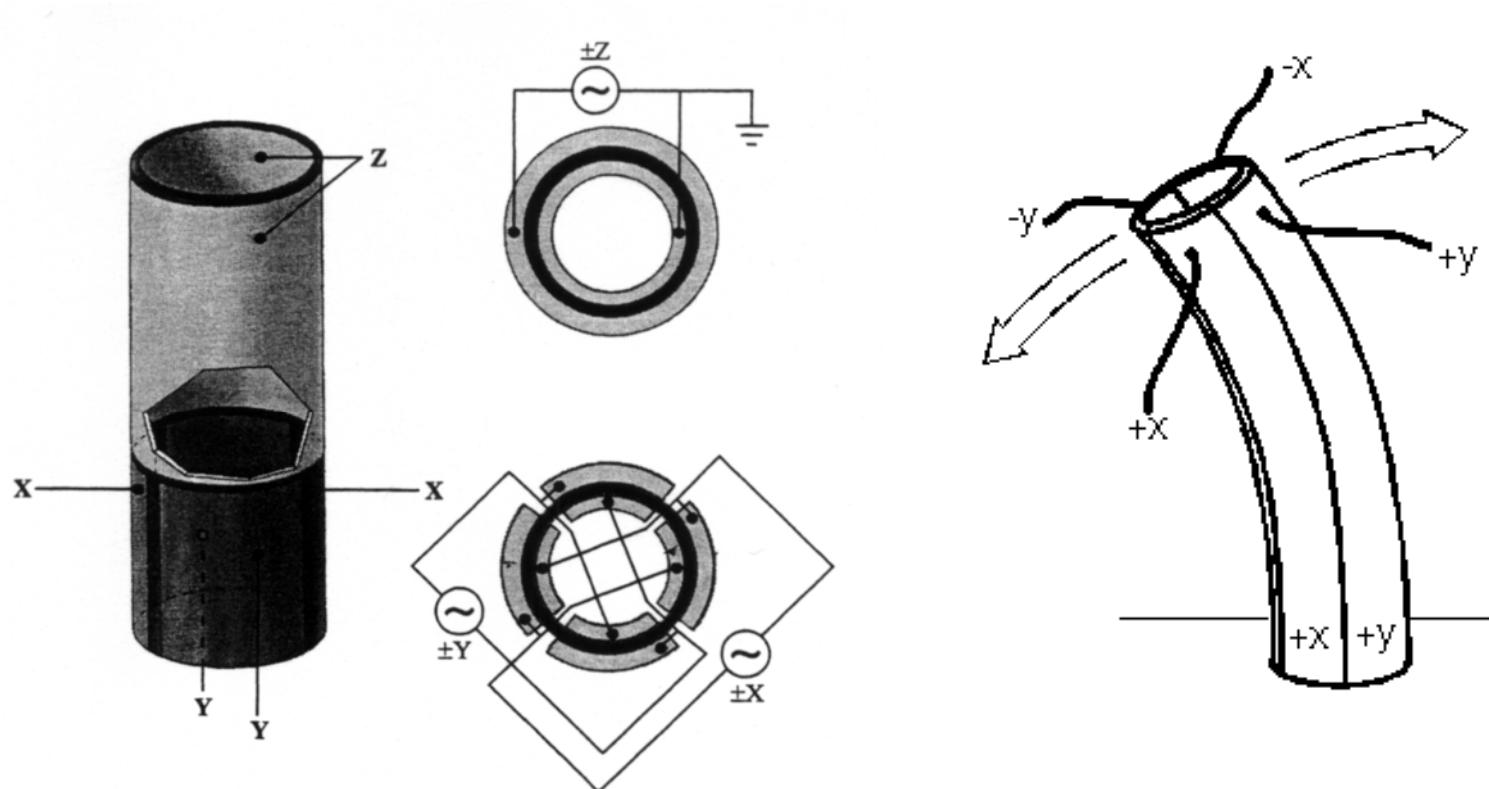


Position-sensitive Photo Diode (PSPD)

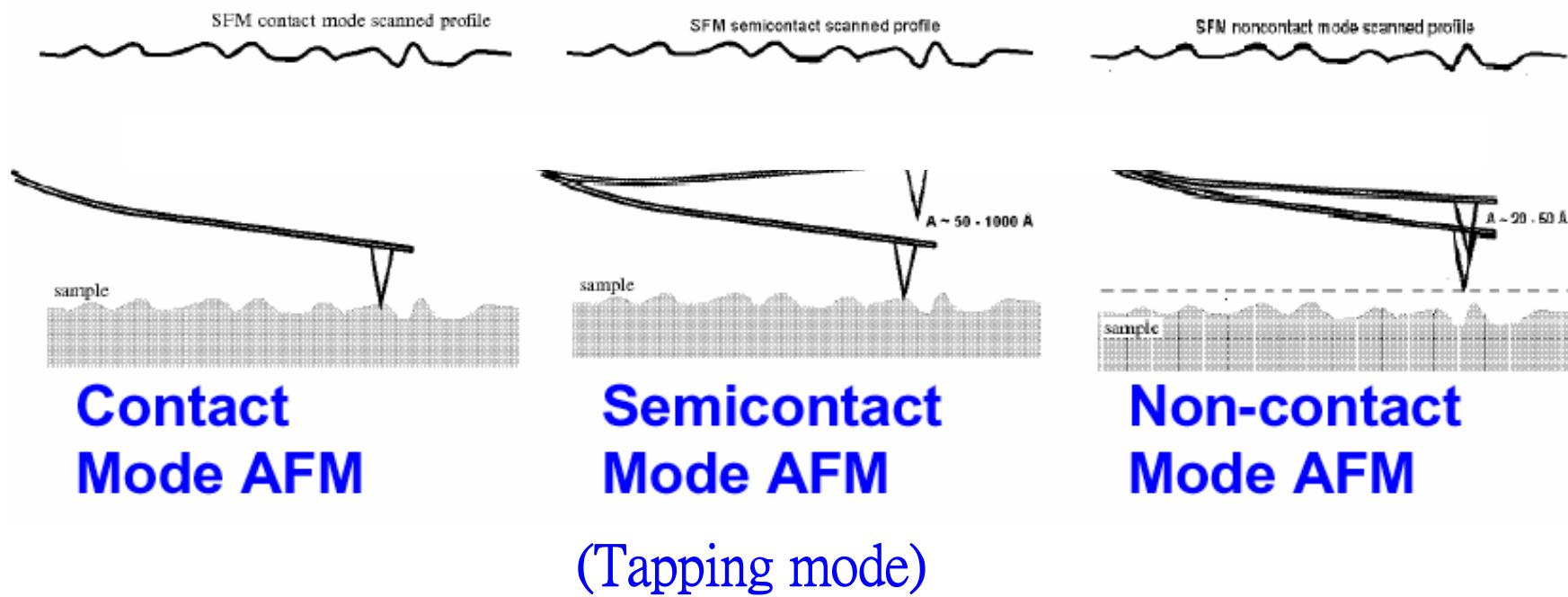


D ~ 10mm d ~ 1mm s ~ 0.01mm

Piezo Scanner



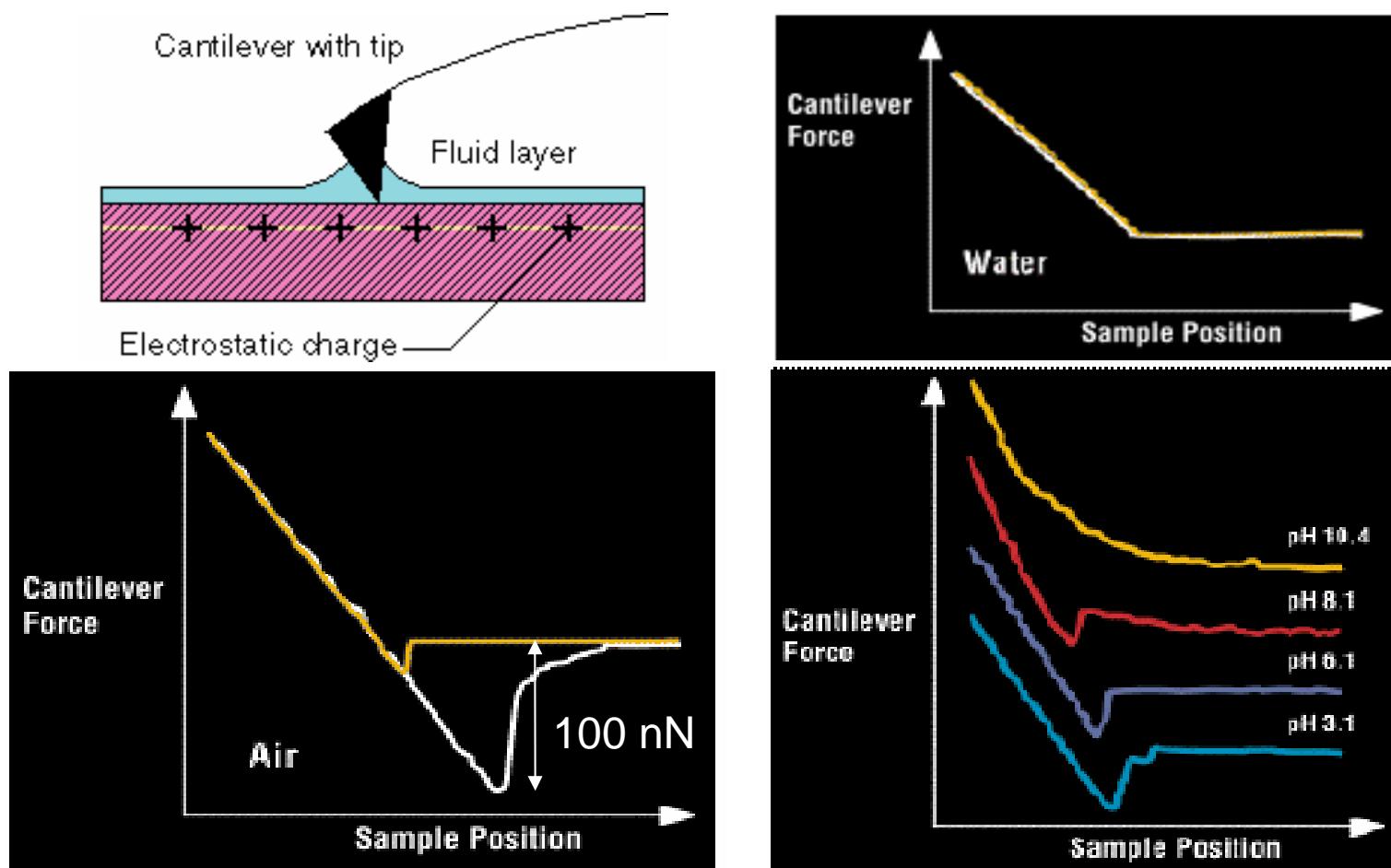
Three scanning modes of AFM



Two imaging methods in contact mode

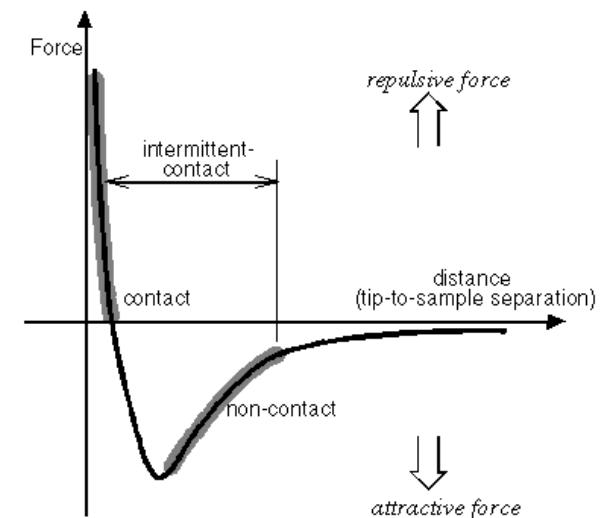
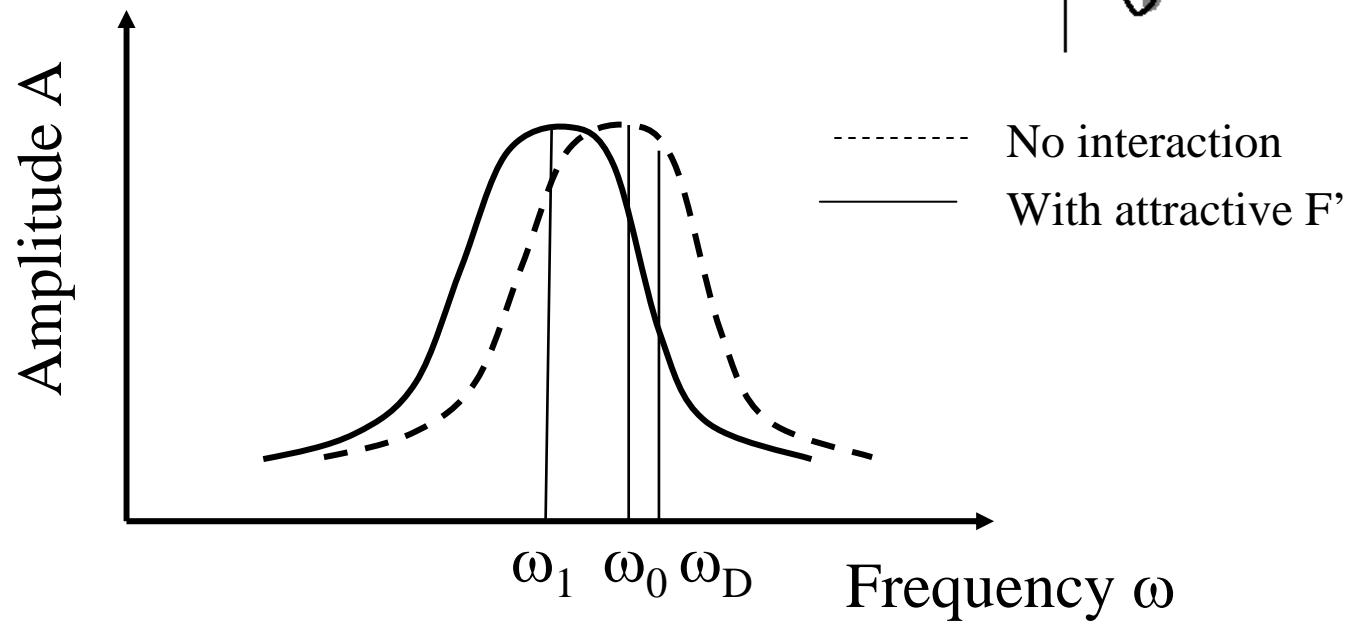
- Constant force method : By using a feedback loop the tip is vertically adjusted in such a way that the force always stays constant. The tip then follows a contour of a constant contact force during scanning. A kind of a topographic image of the surface is generated by recording the vertical position of the tip.
- Constant height method : In this mode the vertical position of the tip is not changed, equivalent to a slow or disabled feedback. The displacement of the tip is measured directly by the laser beam deflection. One of its advantages is that it can be used at high scanning frequencies.

Problems with the contact mode

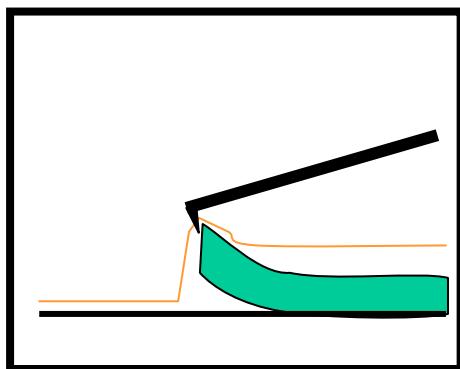


AC imaging mode

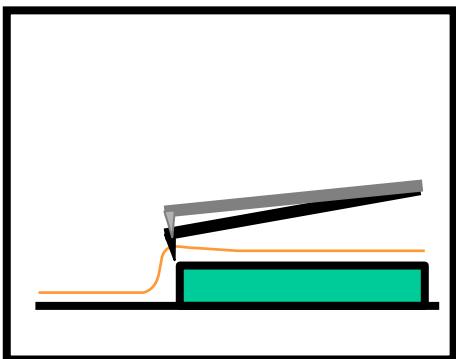
$$\omega_1 = \omega_0 (1 - F'/2c)$$



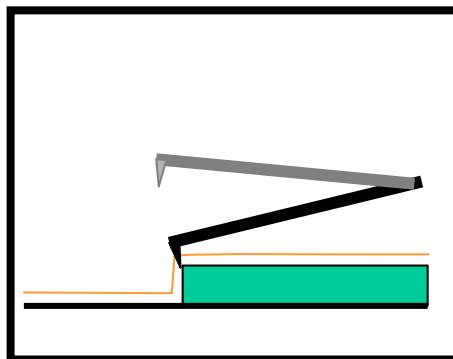
Comparison of three scanning modes



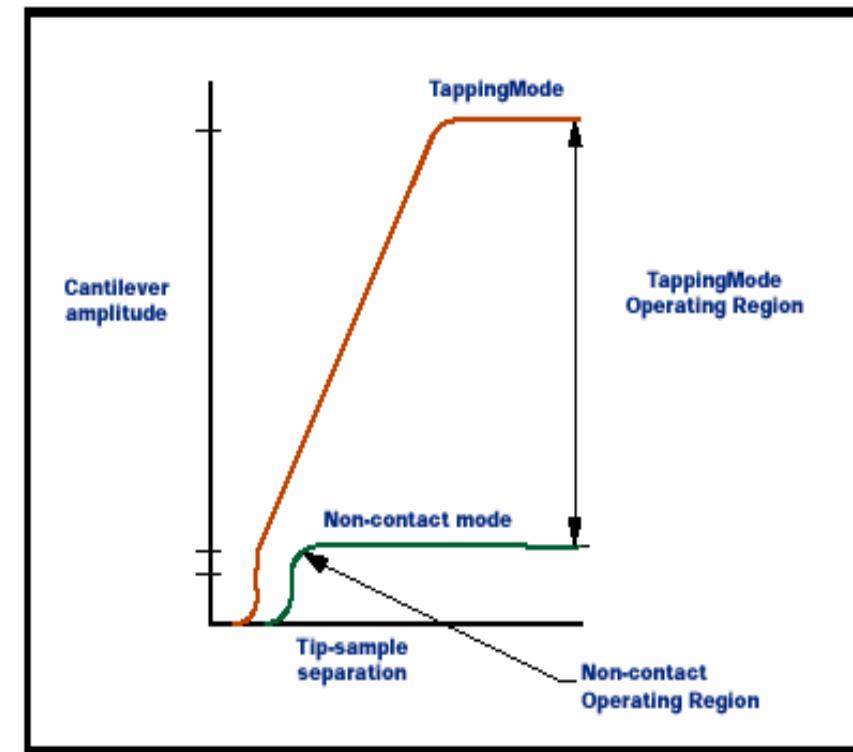
Contact



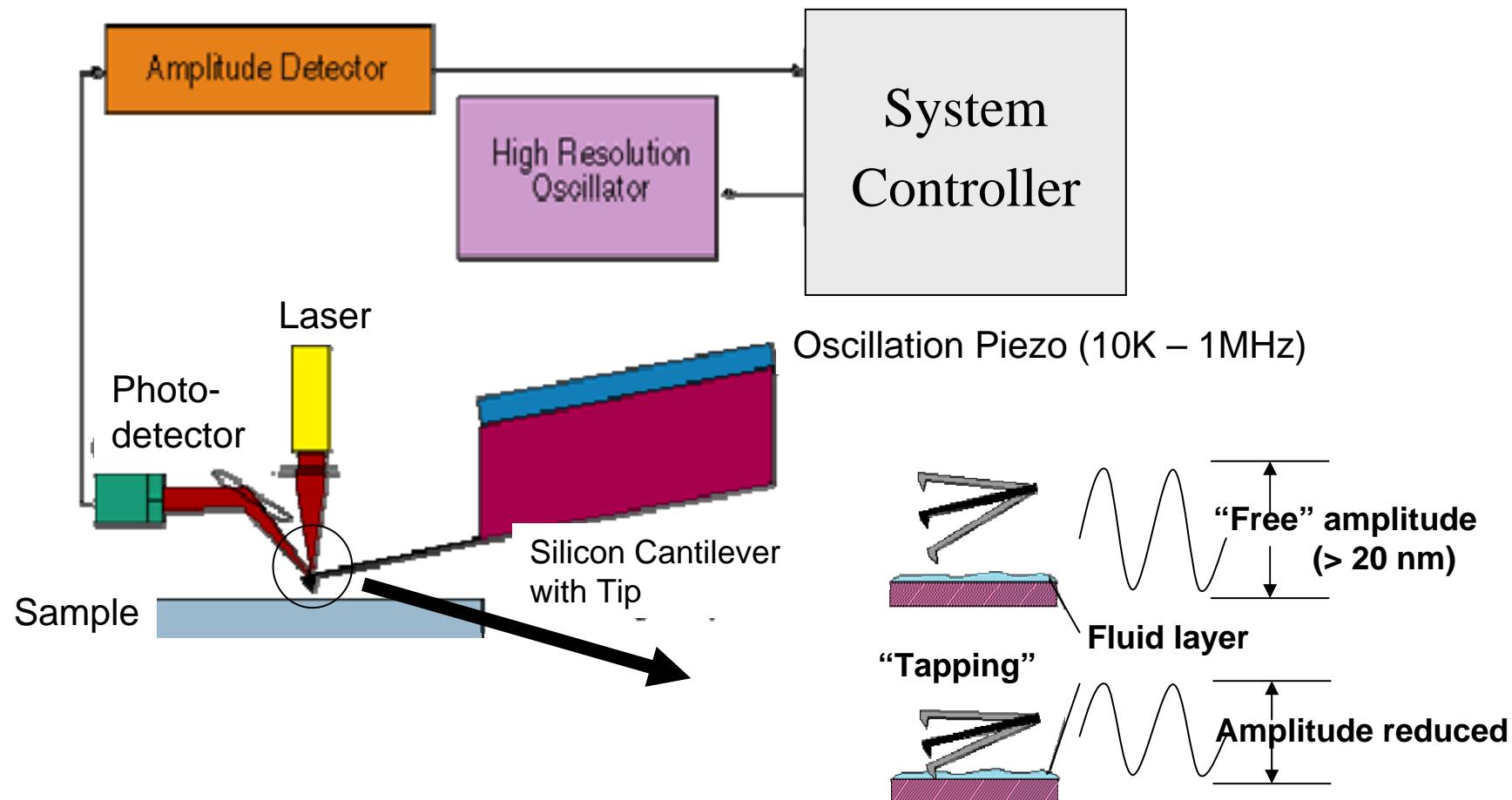
Non-contact



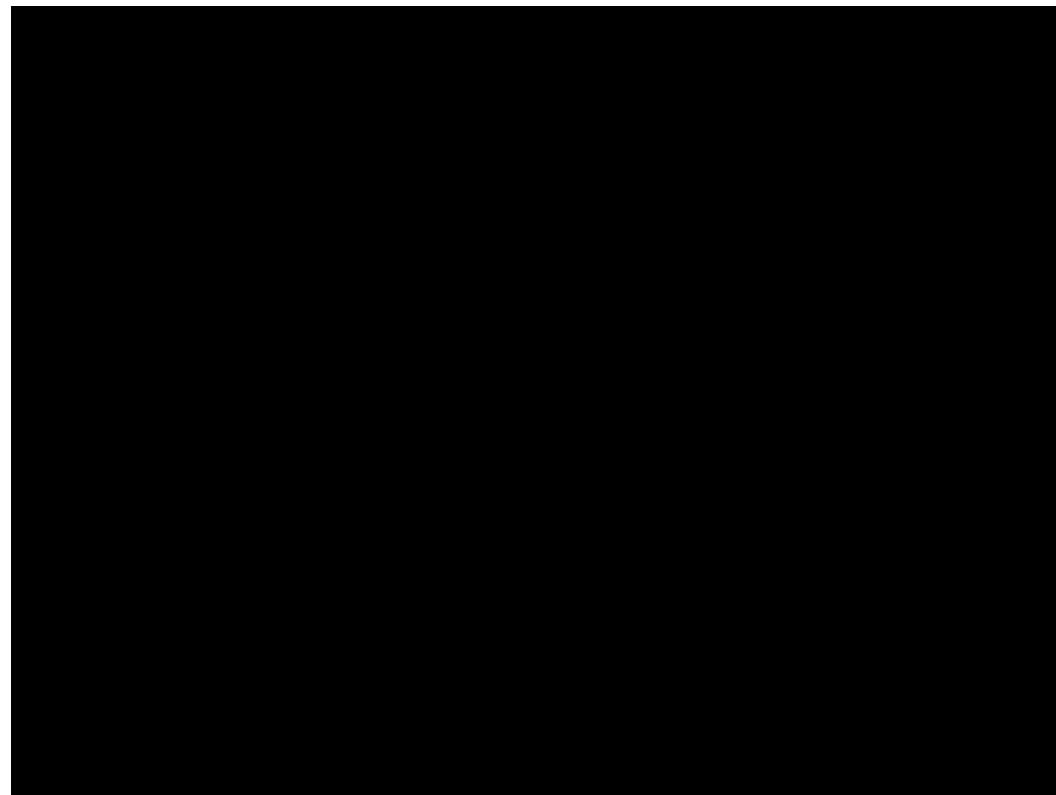
Intermittent-contact



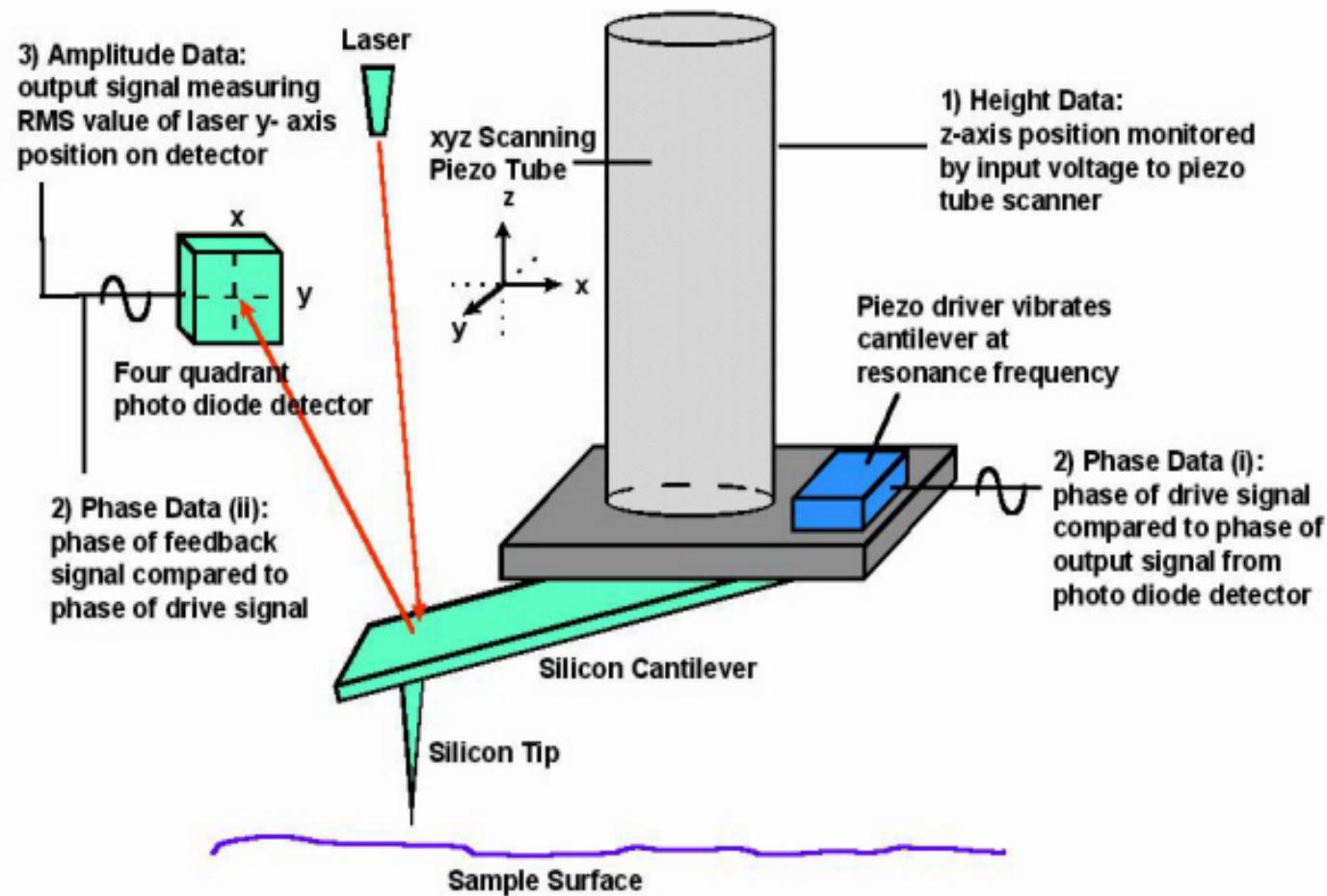
Tapping mode



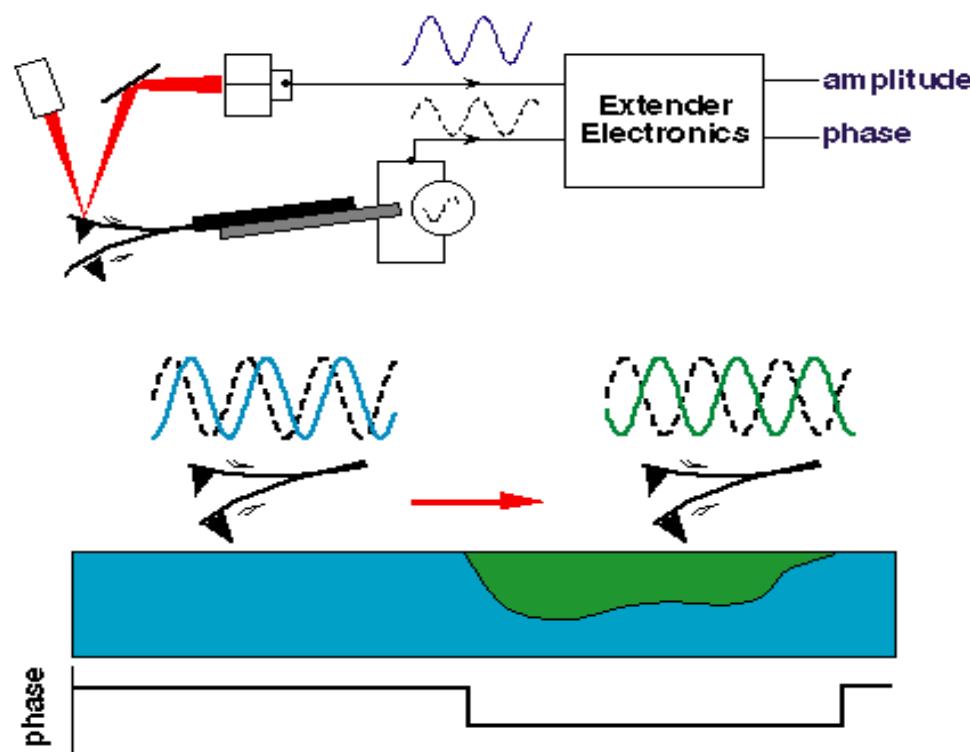
Tapping mode



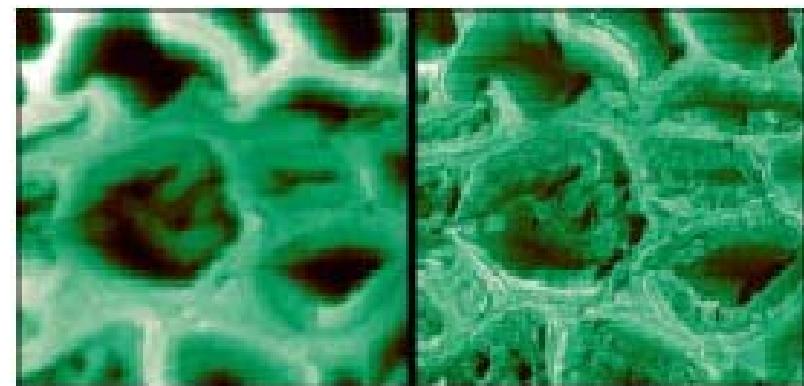
Three Types of Data Collected in Tapping Mode



Images by tapping mode

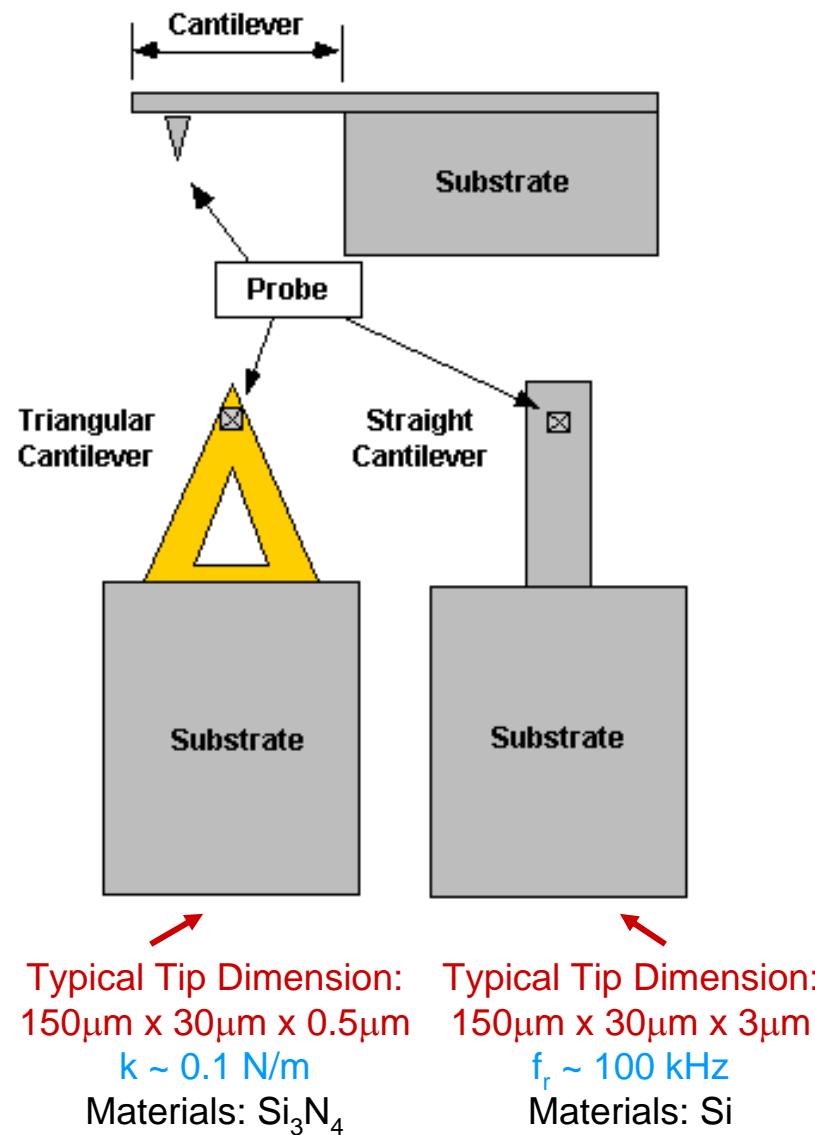
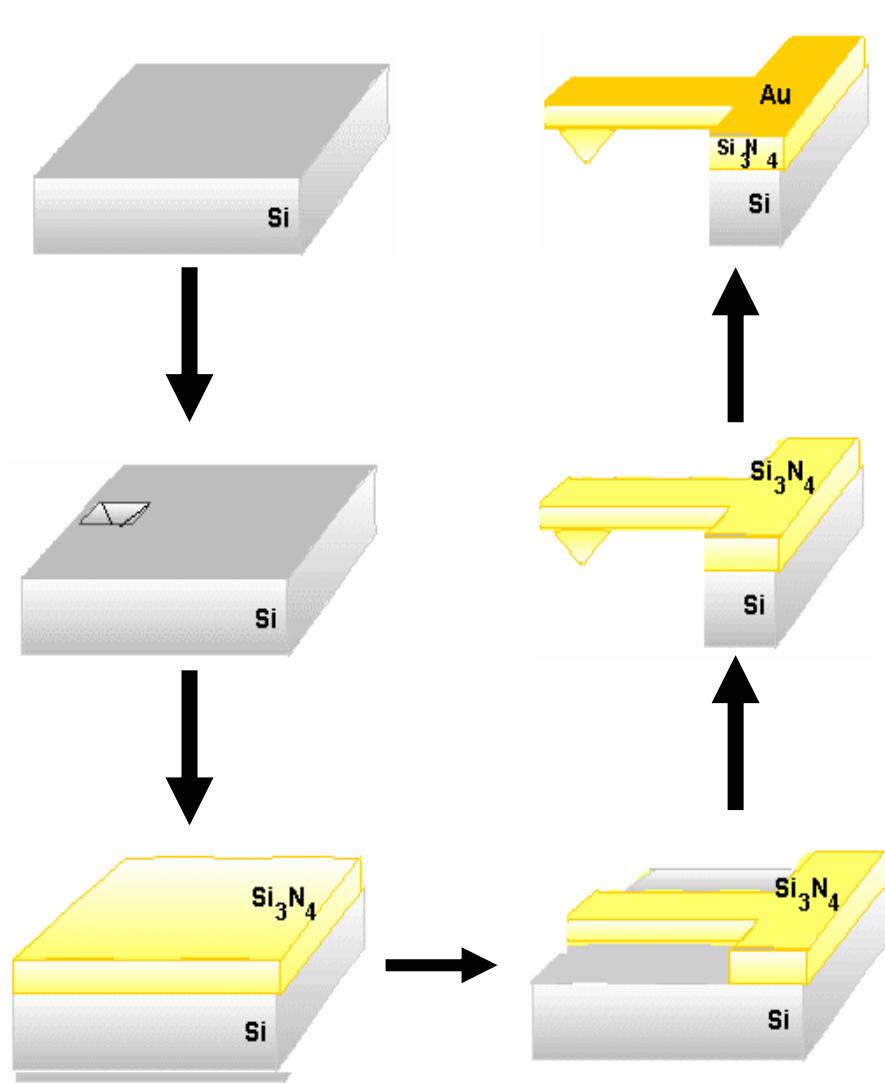


Topography Phase

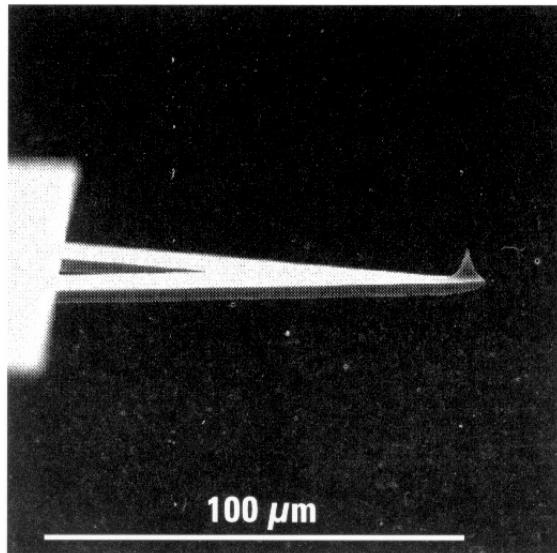


AFM image of a fresh
Alfalfa root section

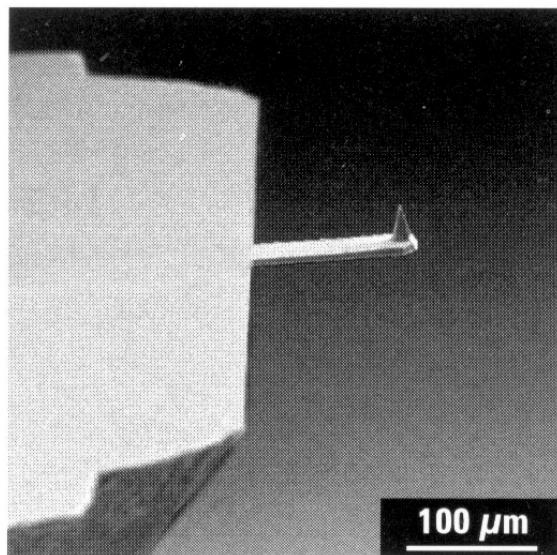
Fabrication of AFM probes



V-shaped



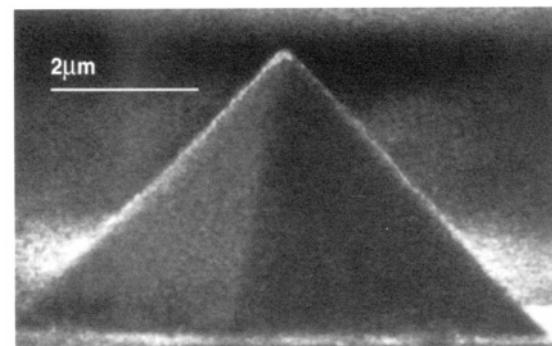
Rectangular-shaped



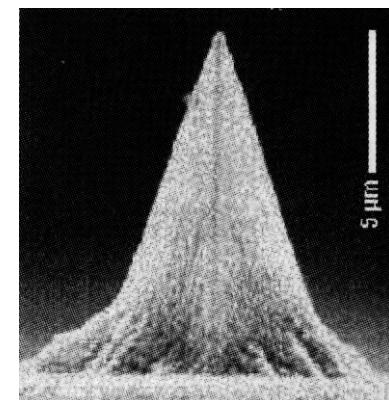
Materials: Si, SiO₂, Si₃N₄

Ideal Tips: hard, small radius of curvature, high aspect ratio

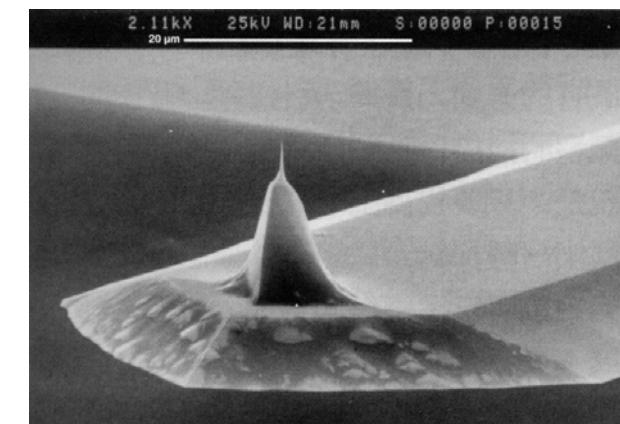
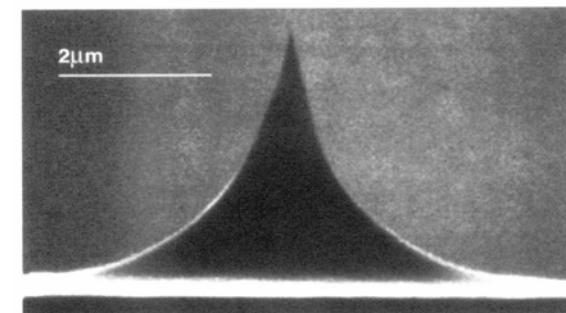
Pyramid Tip



Diamond-coated Tip



Ultrasharp Tip

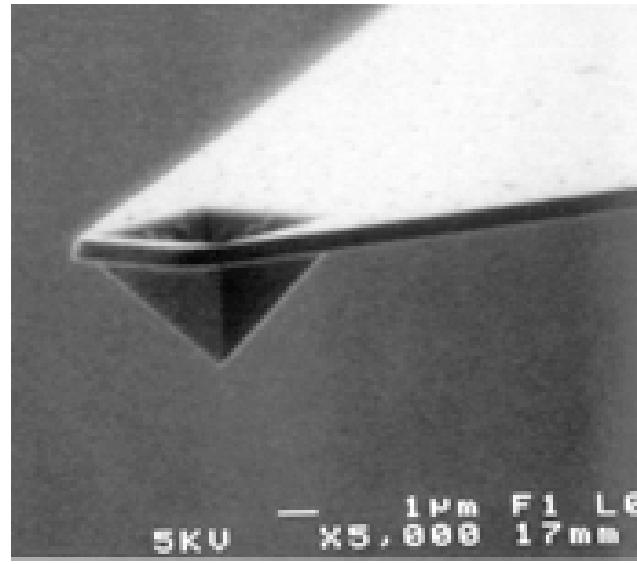
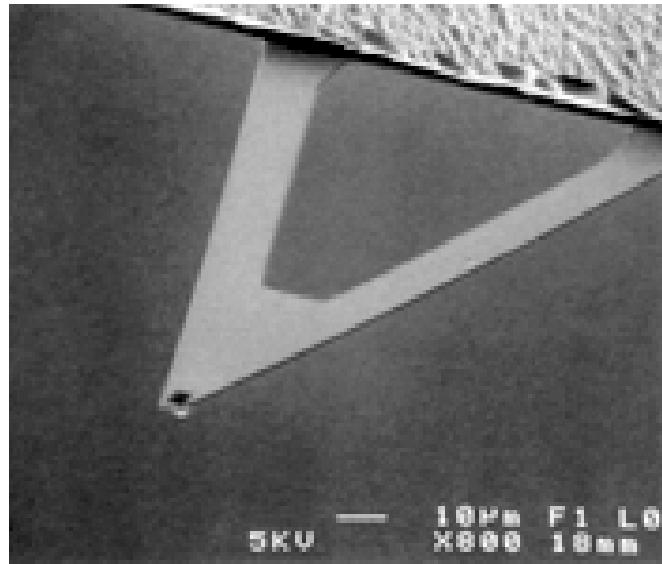


Criteria for AFM probe

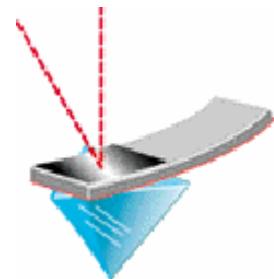
- 1) Small spring constant (k) $F = k \Delta z$
To detect force of $\sim nN$
- 2) High resonant frequency (f_r) $f_r \propto (k/m)^{1/2}$
To enable scanning and other operations
- 3) Highly anisotropic stiffness
Easy to bend and difficult to twist
- 4) Sharp protrusion at the apex
To better define the tip-sample interaction

Tip of small shear force

(for Contact mode)

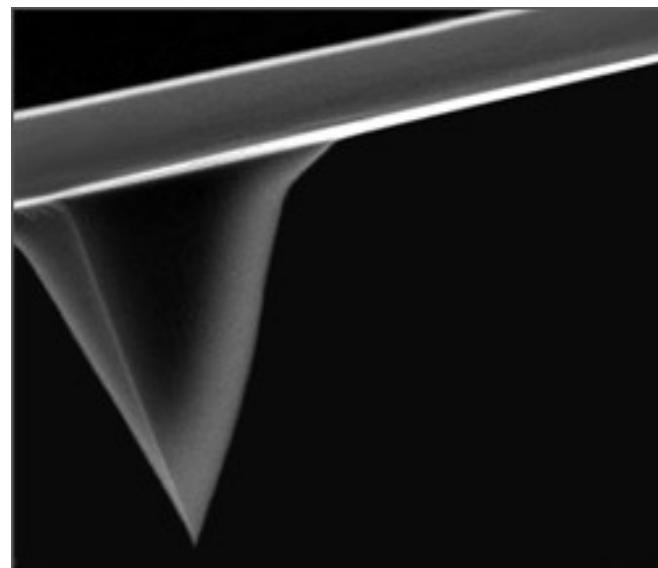
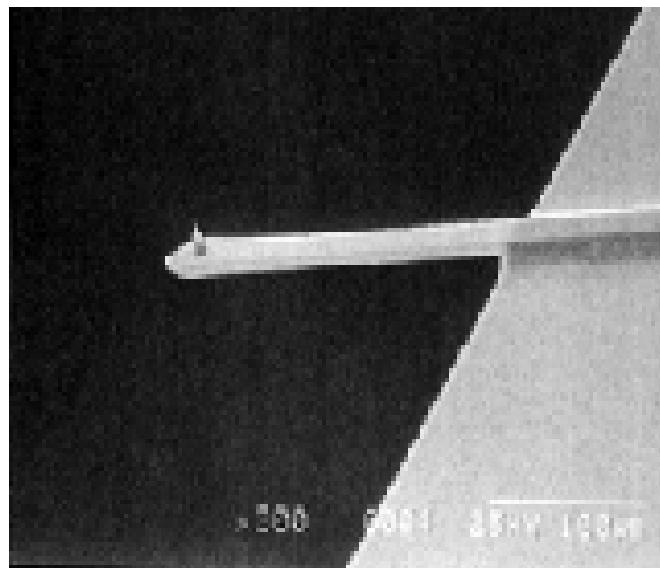


Typical Tip Dimension:
 $150\mu\text{m} \times 30\mu\text{m} \times 0.5\mu\text{m}$
 $k \sim 0.1 \text{ N/m}$
Materials: Si_3N_4

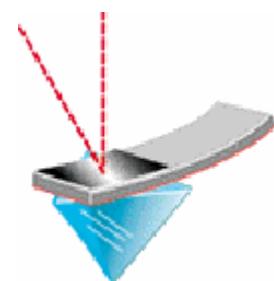


Tip of high resonant frequency

(for Tapping mode)



Typical Tip Dimension:
 $150\mu\text{m} \times 30\mu\text{m} \times 3\mu\text{m}$
 $f_r \sim 100 \text{ kHz}$
Materials: Si



AFM versus STM

1. STM has better resolution than AFM.
2. The force-distance dependence in AFM is much more complex when characteristics such as tip shape and contact force are considered.
3. STM is generally applicable only to conducting samples while AFM is applied to both conductors and insulators.
4. AFM offers the advantage that the writing voltage and tip-to-substrate spacing can be controlled independently, whereas with STM the two parameters are integrally linked.

AFM versus SEM

1. AFM provides extraordinary topographic contrast direct height measurements and SEM provides only 2D mapping of surface features.
2. For insulating samples, no metallic coating is necessary for AFM.

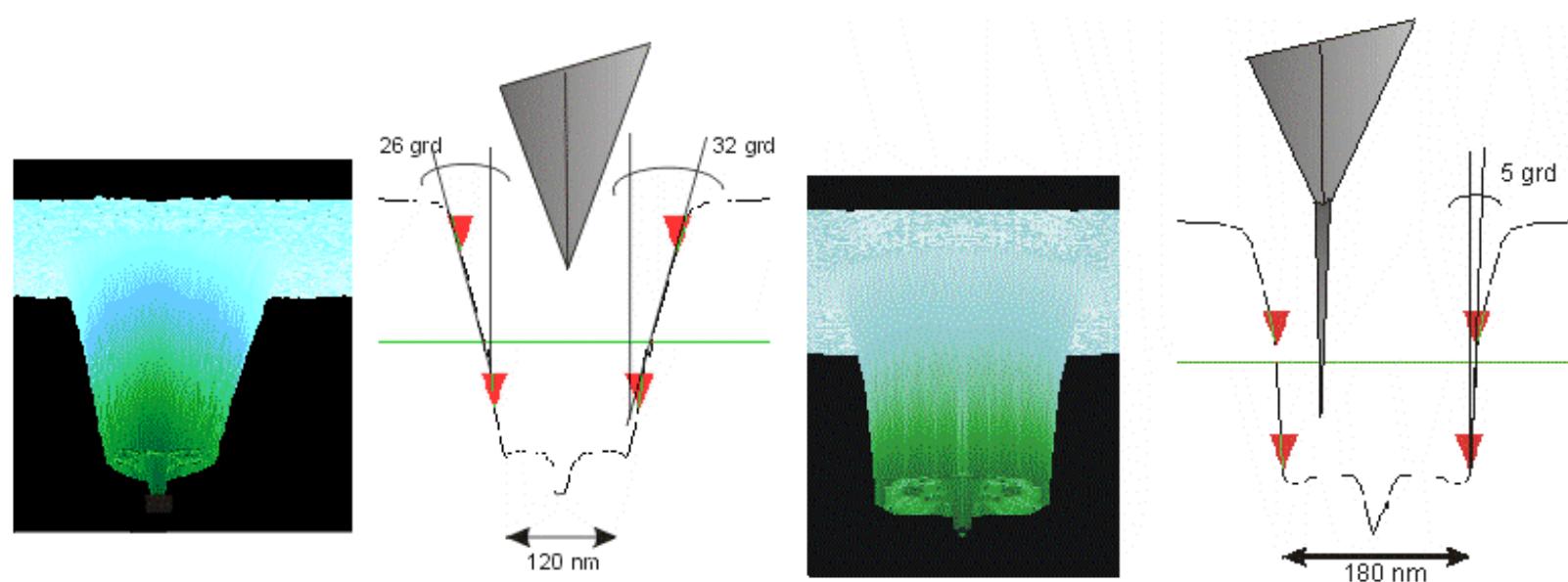
AFM versus TEM

1. Compared with Transmission Electron Microscopes, three dimensional AFM images are obtained without expensive sample preparation and yield far more complete information than the two dimensional profiles available from cross-sectioned samples.
2. No charging effect occurs in AFM.

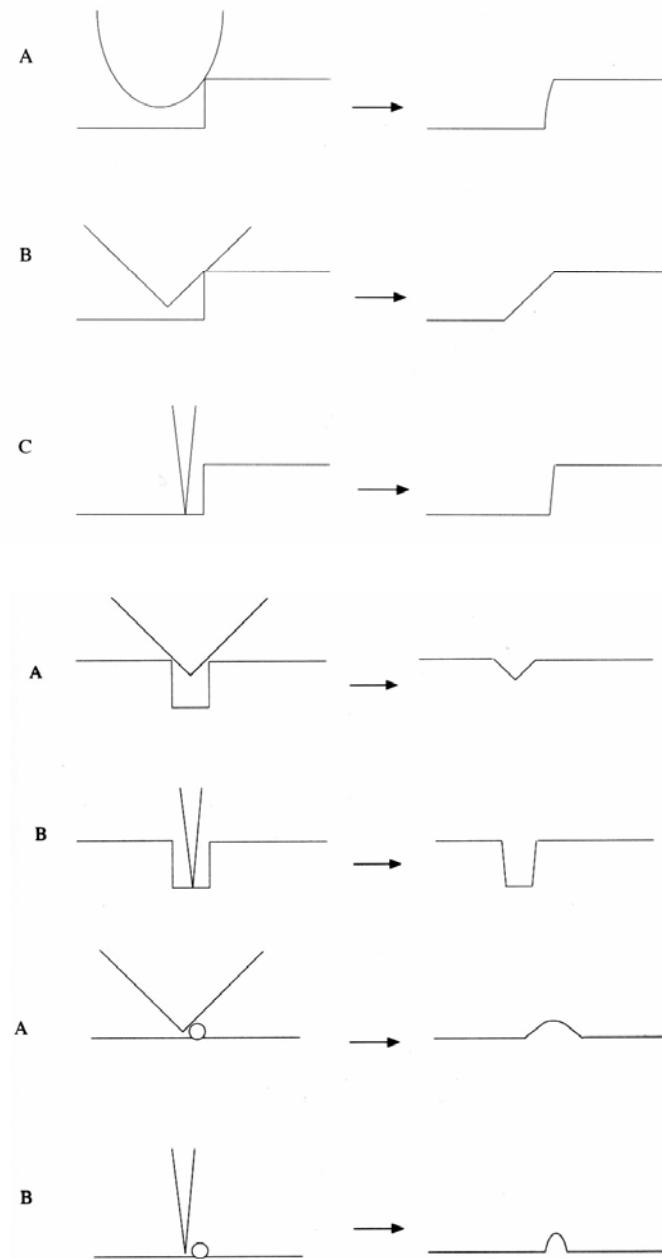
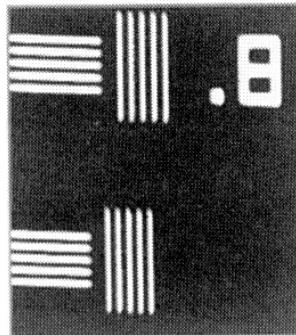
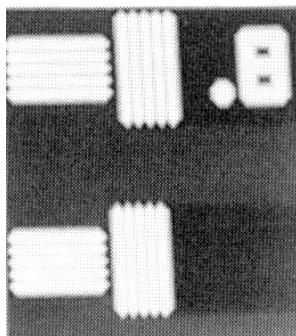
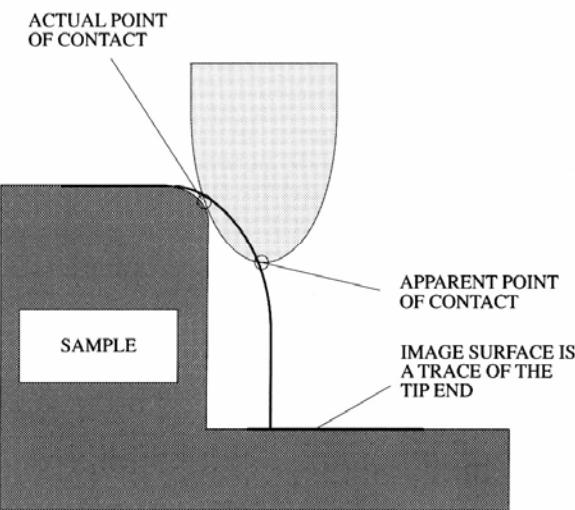
AFM versus Optical Microscope

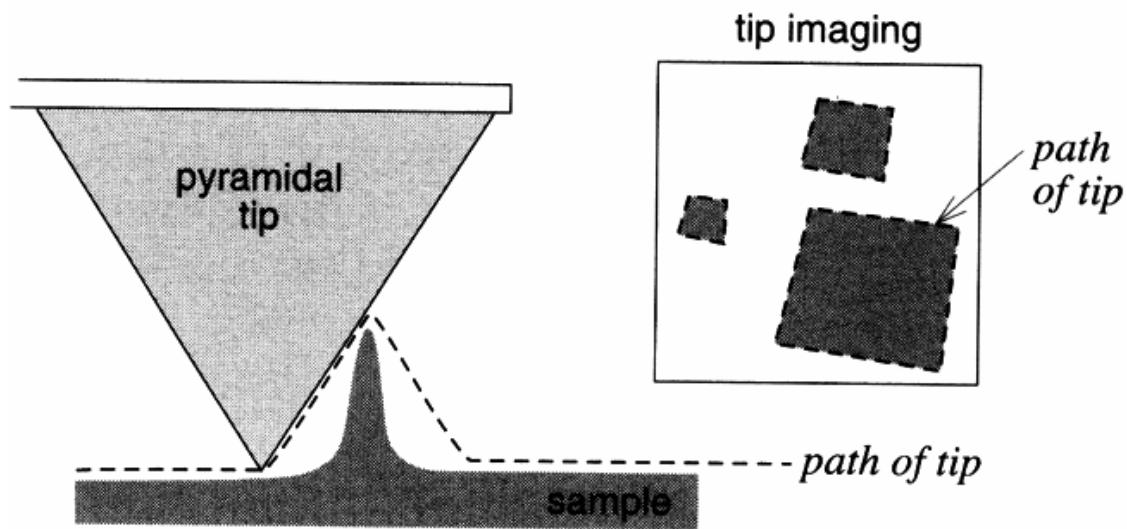
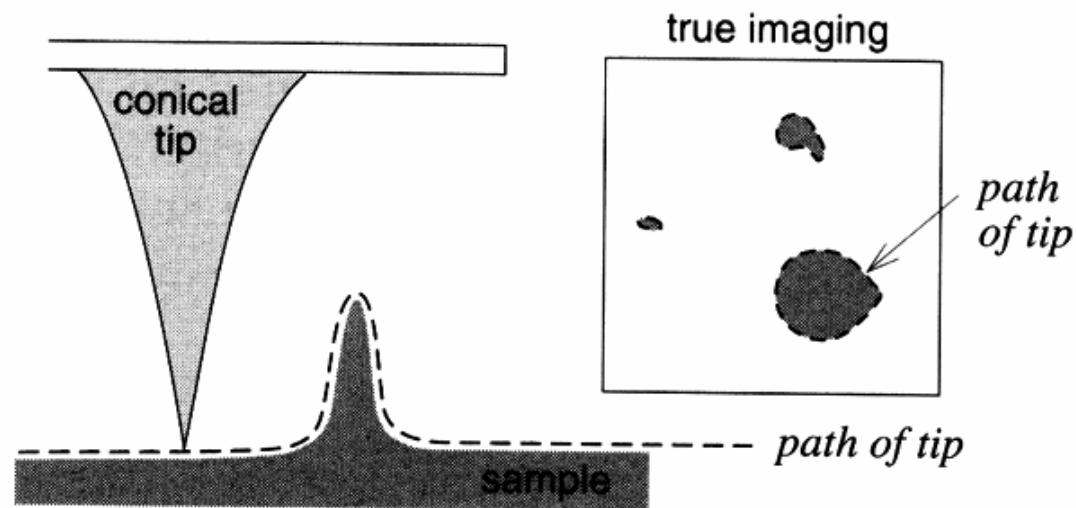
1. AFM has much better resolution than Optical Microscope.
2. AFM provides unambiguous measurement of step heights, independent of reflectivity differences between materials.

Ultra-sharp tip



Effects of the Tip Shape





AFM Tip + Carbon Nanotube

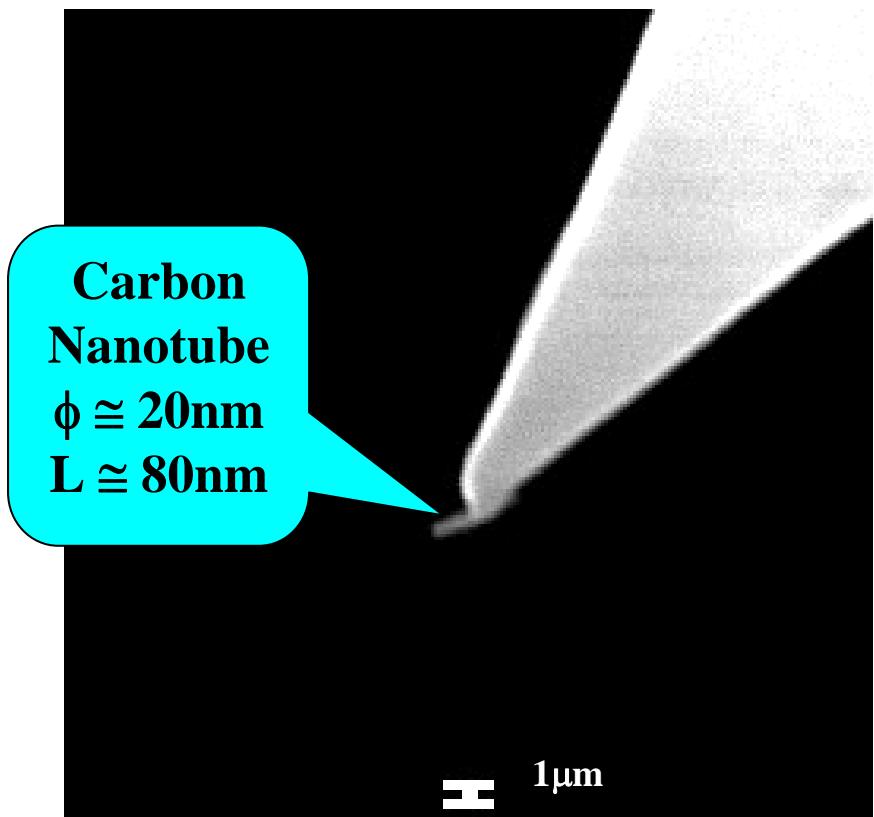
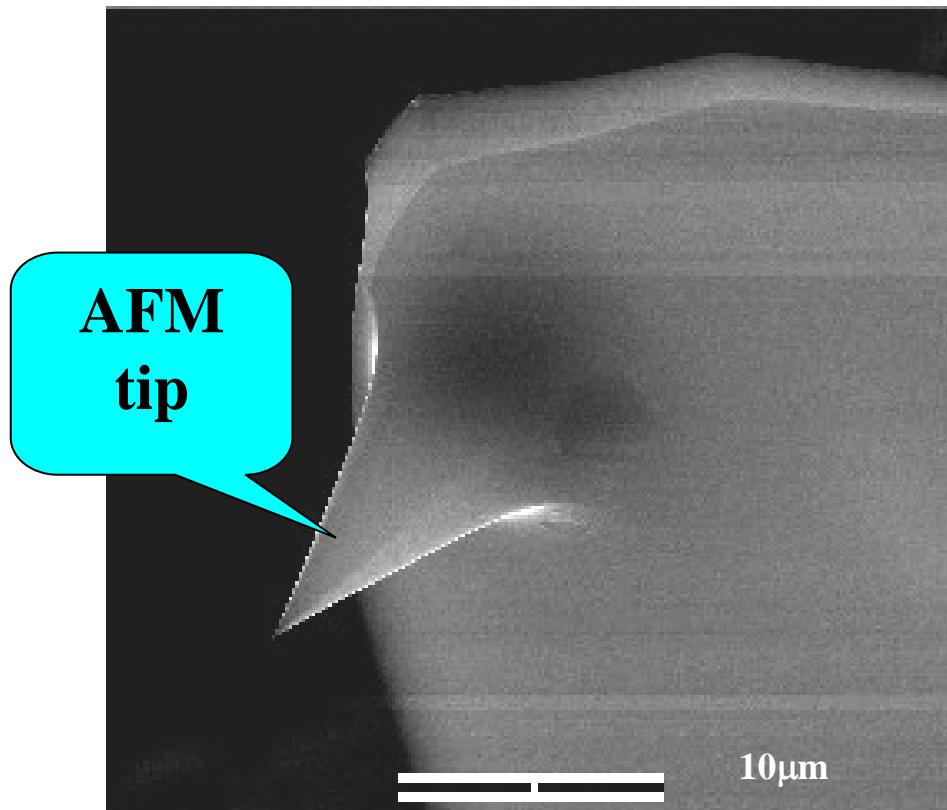
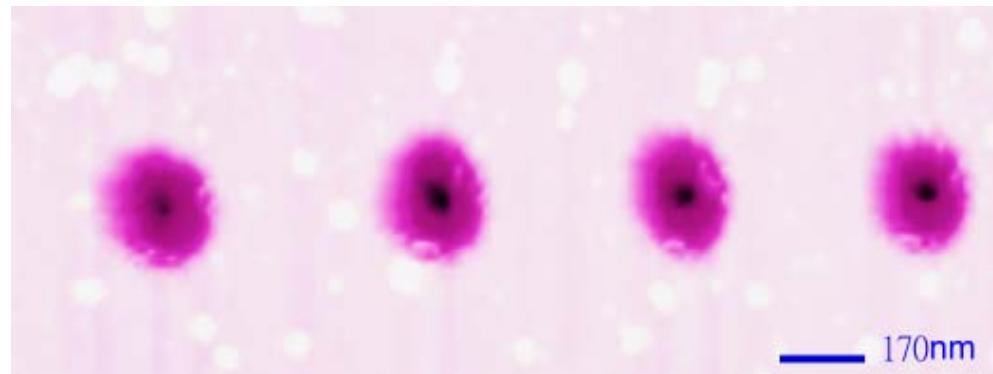
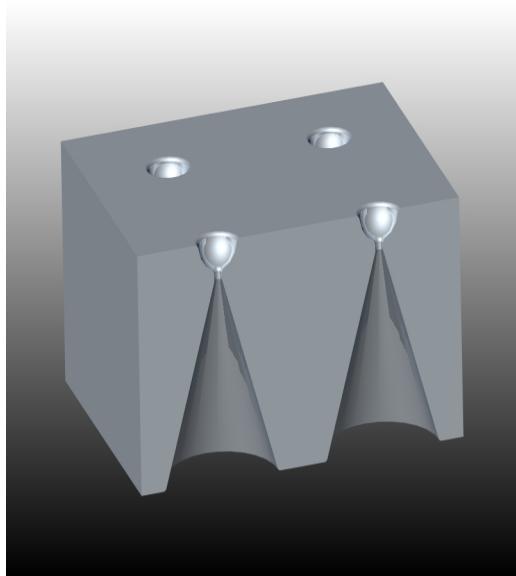
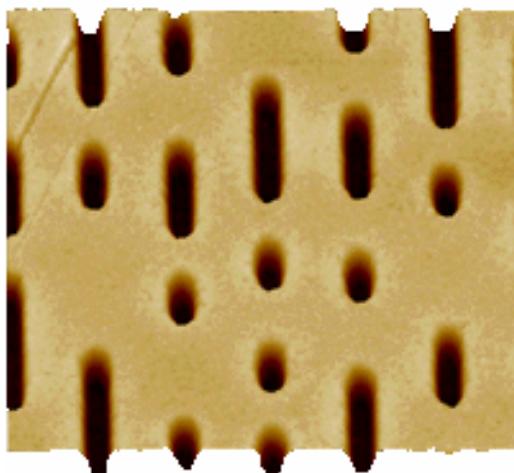


Image of high aspect ratio

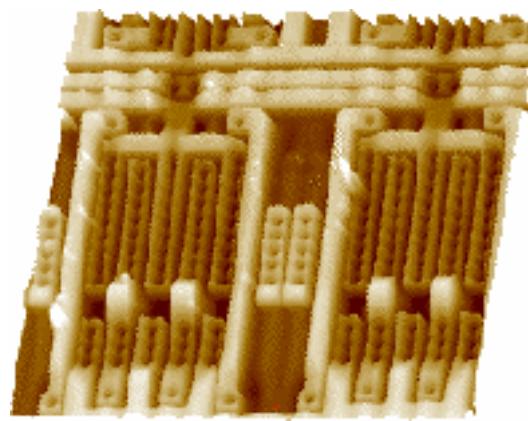


AFM images

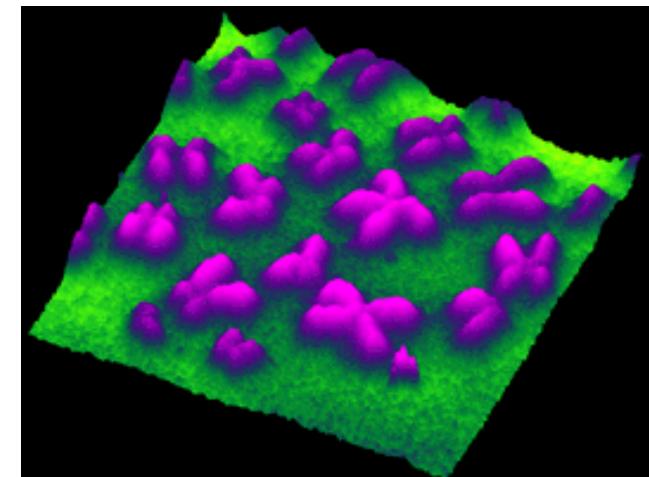
CD pits



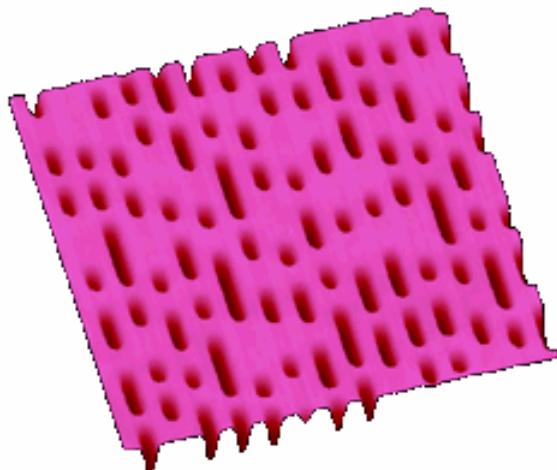
Integrated circuit



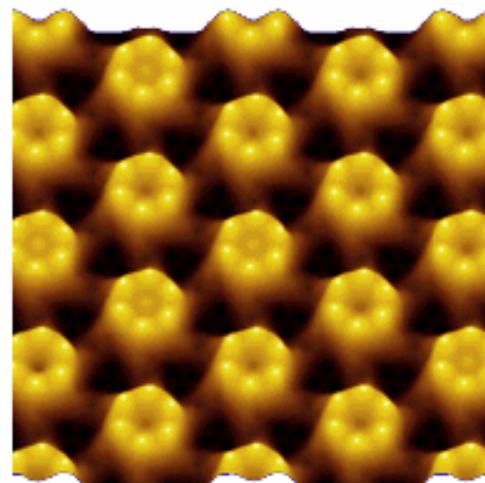
Chromosomes



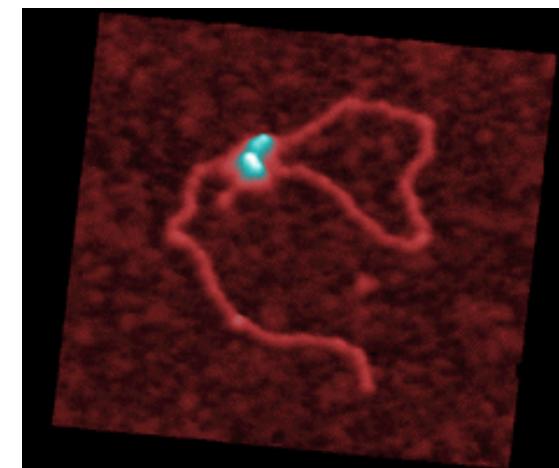
DVD pits



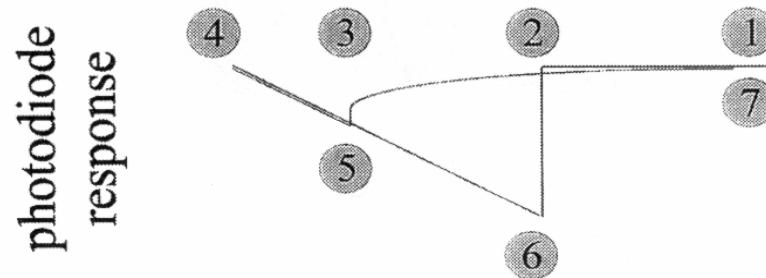
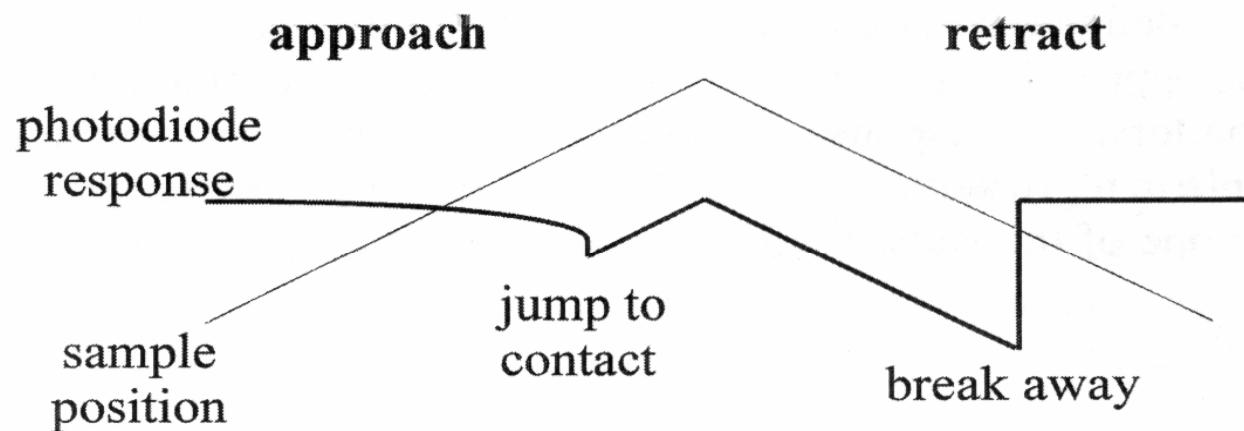
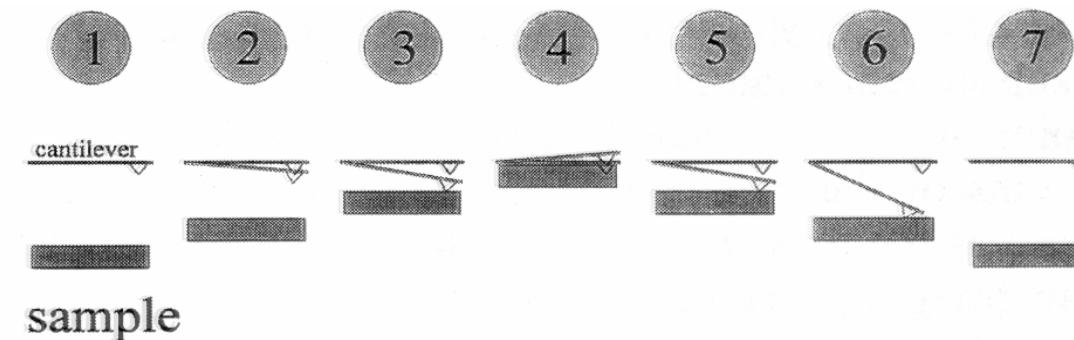
Bacteria



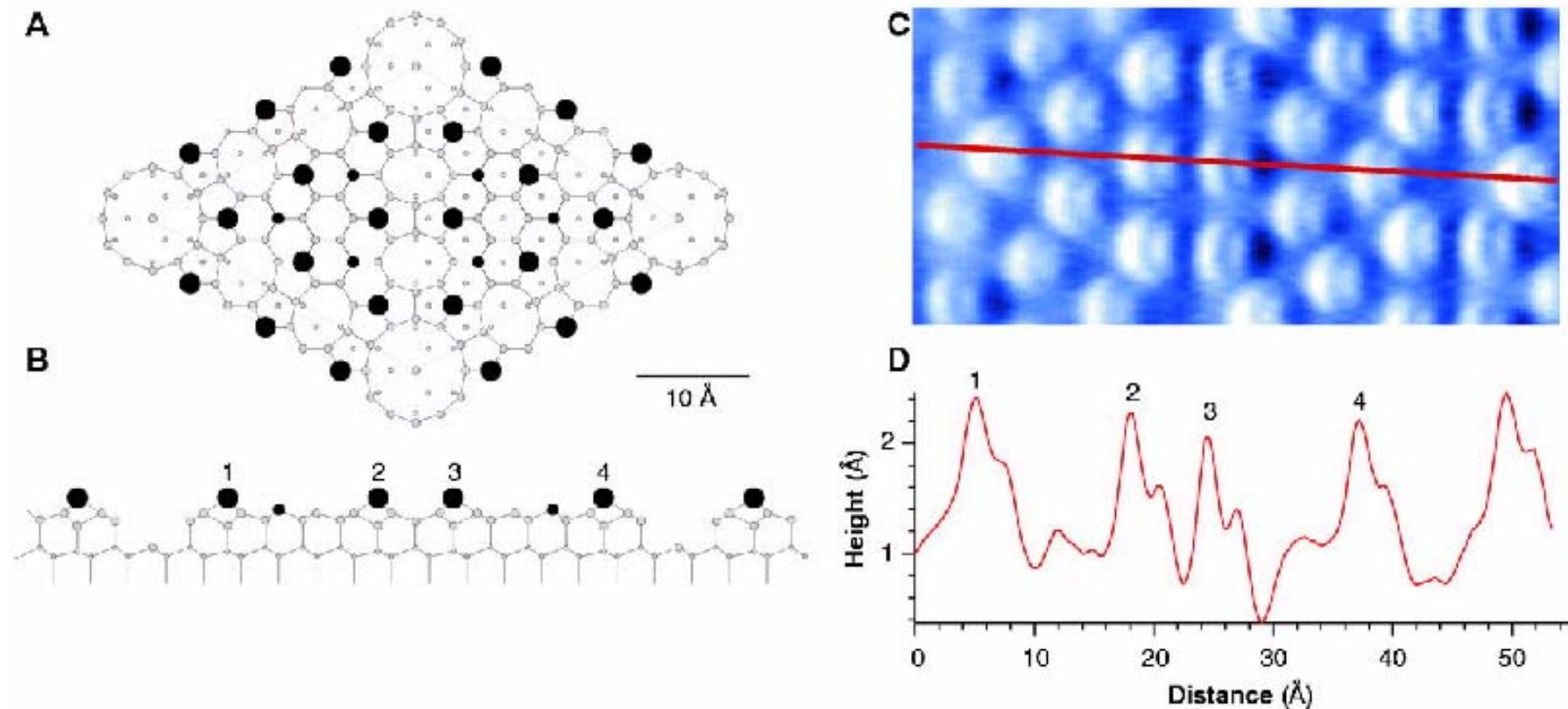
DNA



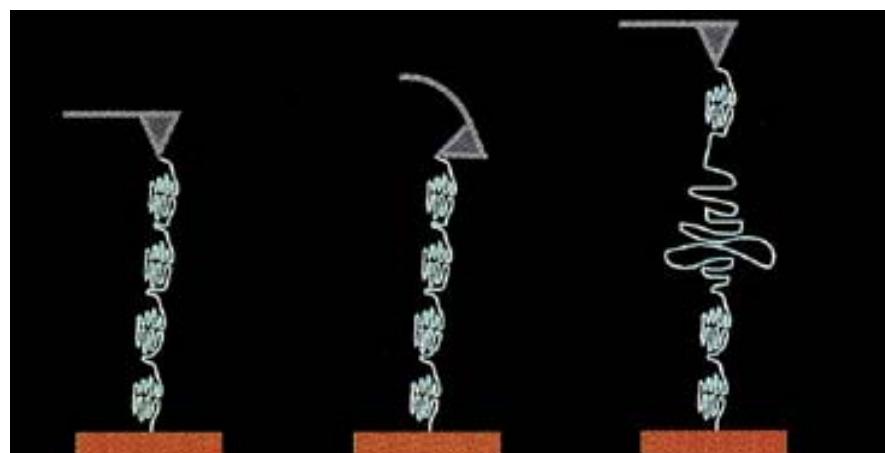
Force-Distance Curve



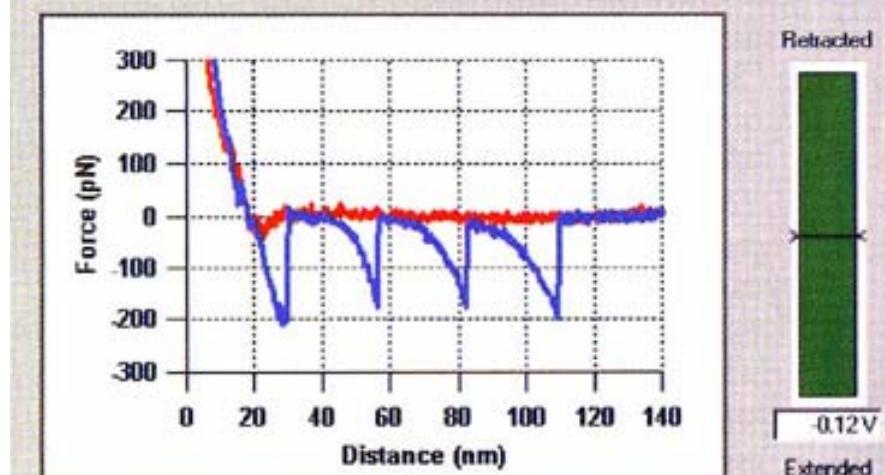
Atomic Image of Si(111)-(7×7) Taken with AFM



F.J. Giessibl *et al.*, *Science* **289**, 422 (2000)

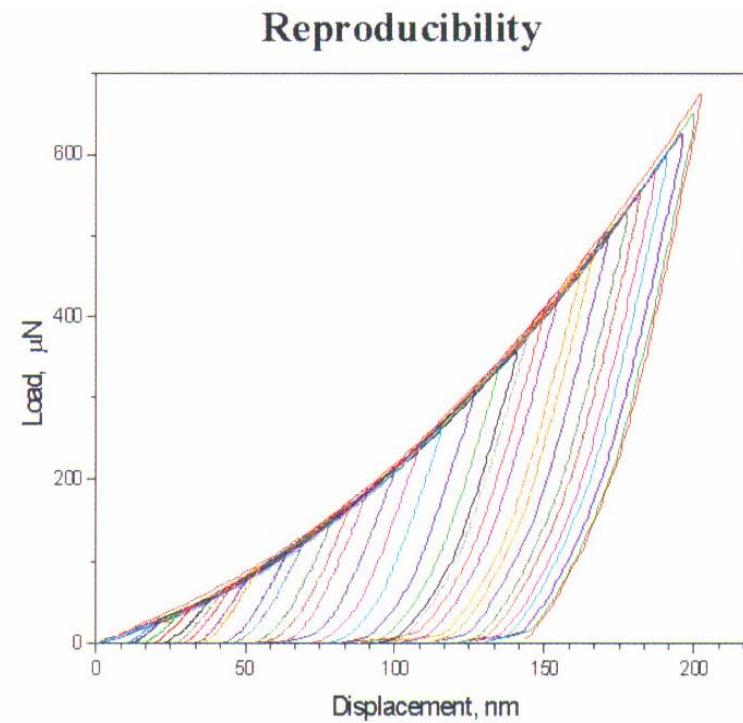
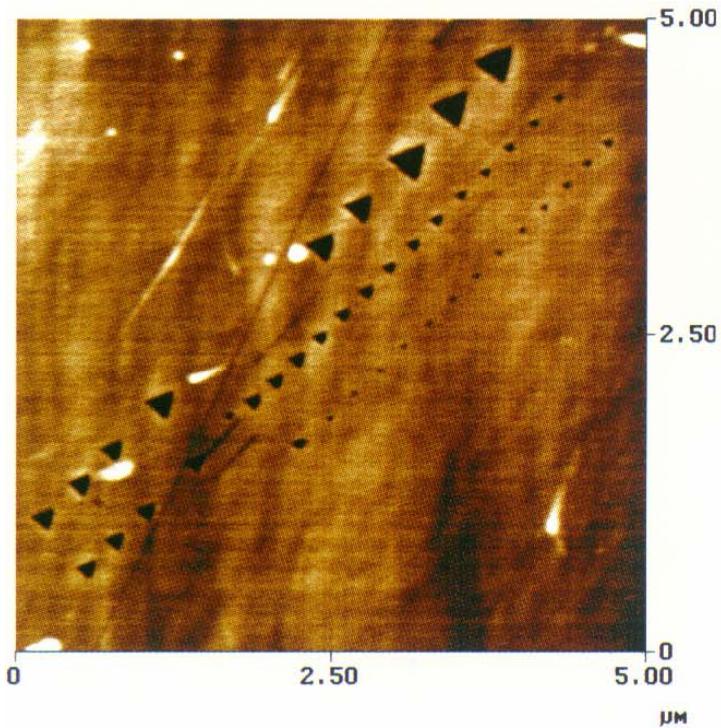


Force measurement of an unfolding complex molecule.



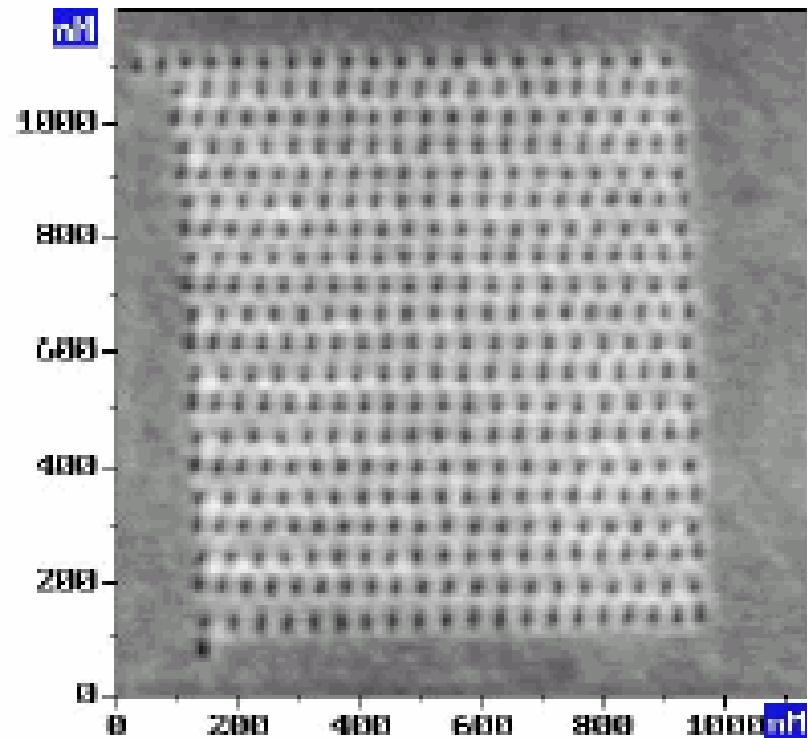
Advanced graphical user interface shows titin muscle molecule force curve.

Measurement of Mechanical Properties

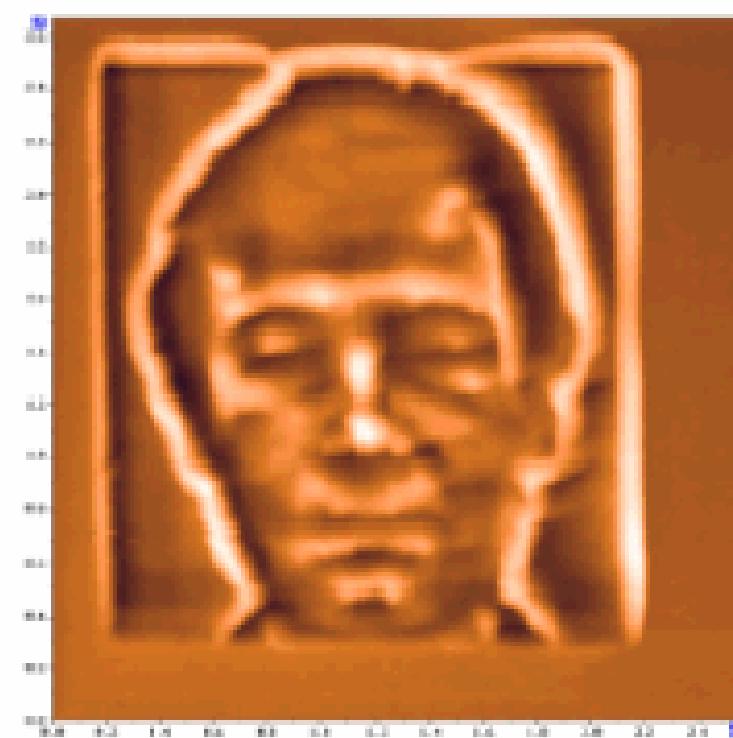


1. The load-displacement curves provide a “mechanical fingerprint” of material’s response to deformation, from which parameters such as hardness and young’s modulus of elasticity can be determined.
2. In measuring the mechanical properties of thin coated system, the size of contact impression should be kept small relative to the film thickness.

Nanolithography of Tapping-Mode AFM



$(1.2 \mu \text{m} \times 1.2 \mu \text{m})$



$(2.5 \mu \text{m} \times 2.5 \mu \text{m})$

Image of polycarbonate film on silicon surface